The public reporting burden for this collection of information is estimated to everage 1 hour per response, including the lime for reviewing miss according action gratering and maintaining the data needed, and combining and reviewing the collection of information. Send congustring this burden estimate or any other aspect of this collection of information, including suggestations for reducing this hurden to the collection of information including suggestations for reducing this hurden. The collection of information in collection i	REPORT DOCUMENTATION PAGE Fo				orm Approved OMB NO. 0704-0188		
10-12-2009  4. TITLE AND SUBTITLE Proceedings of 4th IEEE International Conference on Nanotechnology  5a. CONTRACT NUMBER W911NF-04-1-0094  5b. GRANT NUMBER  5c. PROGRAM ELEMENT NUMBER 611102  6. AUTHORS Paolo LUGLI  6. AUTHORS Paolo LUGLI  7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESSES TUS. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.	searching existing data sources, gathering and mair regarding this burden estimate or any other asport Headquarters Services, Directorate for Information Respondents should be aware that notwithstanding any information if it does not display a currently valid OMB control.	ntaining the data needed, ect of this collection of Operations and Report of other provision of law, no ol number.	and completing and information, including ts, 1215 Jefferson Da	revie sug avis	wing the collection of information. Send comments gesstions for reducing this burden, to Washingtor Highway, Suite 1204, Arlington VA, 22202-4302.		
10-12-2009   Final Report   17-May-2004 - 16-May-2005   4. TITLE AND SUBTITLE   5a. CONTACT NUMBER   W911NF-04-1-0094   5b. GRANT NUMBER   Sc. PROGRAM ELEMENT NUMBER   Sc. PROGRAM ELEMENT NUMBER   Sc. PROGRAM ELEMENT NUMBER   Sc. PROGRAM ELEMENT NUMBER   Sc. TASK	1. REPORT DATE (DD-MM-YYYY)	2. REPORT TYPE			3. DATES COVERED (From - To)		
4. TITLE AND SUBTITLE Proceedings of 4th IEEE International Conference on Nanotechnology  8		Final Report			· · · · · · · · · · · · · · · · · · ·		
Proceedings of 4th IEEE International Conference on Nanotechnology  8th IIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIII	4. TITLE AND SUBTITLE	·	5a. CON	JTRA	ACT NUMBER		
Nanotechnology  5b. GRANT NUMBER  5c. PROGRAM ELEMENT NUMBER 611102  6. AUTHORS Paolo LUGLI  5c. TASK NUMBER  10. SPONSORING ORGANIZATION NAMES AND ADDRESSES 10. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESSES 10. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES)  10. SPONSORING/MONITORING AGENCY NAME(S) AND ARO  11. SPONSOR/MONITOR'S ACRONYM(S) ARO  12. DISTRIBUTION AVAILIBILITY STATEMENT  Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES 14. ABSTRACT	Proceedings of 4th IEEE International Conf	W911NF-04-1-0094					
5c. PROGRAM ELEMENT NUMBER 611102  6. AUTHORS Paolo LUGLI  6. AUTHORS Paolo LUGLI  5c. TASK NUMBER  5c. TASK NUMBER  5c. TASK NUMBER  7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES)  U.S. ATMY Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT							
6. AUTHORS Paolo LUGLI  6. AUTHORS Paolo LUGLI  7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES) U.S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT							
6. AUTHORS Paolo LUGLI  5c. TASK NUMBER  5c. TASK NUMBER  7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES) U.S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT			5c. PRO	GRA	M ELEMENT NUMBER		
Paolo LUGLI  5e. TASK NUMBER  5f. WORK UNIT NUMBER  7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES)  U.S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT				611102			
5e. TASK NUMBER  5f. WORK UNIT NUMBER  7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES) U.S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.	6. AUTHORS 56			i. PROJECT NUMBER			
7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES) U.S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT	Paolo LUGLI						
7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES) U.S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited 13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT	5e. T			ASK NUMBER			
7. PERFORMING ORGANIZATION NAMES AND ADDRESSES TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES) U.S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited 13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.							
TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 80333 -  9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES) U.S. Army Research Office P.O. Box 12211 Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.	5f. W			ORK UNIT NUMBER			
Research Triangle Park, NC 27709-2211  12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT	TECHNICAL UNIVERSITY OF MUNICH - Ins Institute of Nanoelectronics Technical University of Munich Munich, DD 8033  9. SPONSORING/MONITORING AGENCY NA ADDRESS(ES) U.S. Army Research Office	3 -		10. S Al	SPONSOR/MONITOR'S ACRONYM(S) RO SPONSOR/MONITOR'S REPORT		
12. DISTRIBUTION AVAILIBILITY STATEMENT Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT							
Approved for Public Release; Distribution Unlimited  13. SUPPLEMENTARY NOTES  The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT	12 DISTRIBUTION AVAILIBILITY STATEMEN	 NT			<u> </u>		
13. SUPPLEMENTARY NOTES  The views, opinions and/or findings contained in this report are those of the author(s) and should not contrued as an official Department of the Army position, policy or decision, unless so designated by other documentation.  14. ABSTRACT							
	13. SUPPLEMENTARY NOTES The views, opinions and/or findings contained in th	is report are those of the a		ot co	entrued as an official Department		
		I the extended abstrac	ets of the conference	ee			
15. SUBJECT TERMS	15. SUBJECT TERMS						
Nanotechnology							
16. SECURITY CLASSIFICATION OF: a. REPORT b. ABSTRACT c. THIS PAGE  17. LIMITATION OF OF PAGES OF PAGES OF PAGES OF PAGES OF Page 19a. NAME OF RESPONSIBLE PERSON PAGE 19a. NAME				- 1			

UU

UU

UU

UU

19b. TELEPHONE NUMBER

000-000-0000

Getting Started

Conference Info

Authors

Sessions

Sponsors

2004 Fourth IEEE Conference on Nanotechnology

17– 19 August 2004 Tutorials – 16 August 2004 Technische Universität München Munich, Germany

© 2004 IEEE. Personal use of this material is permitted. However, permission to reprint/republish this material for advertising or promotional purposes or for creating new collective works for resale or redistribution to servers or lists, or to reuse any copyrighted component of this work in other works must be obtained from the IEEE.

Sponsors



Institute of Electrical and Electronics **Engineers** 



**IEEE Nanotechnology Council** 

Co-Sponsors SIEMENS
Siemens AG Corporate Technology





**General Electric Deutschland** 



**European Office of Aerospace** 

Research and Development (EOARD)

U.S. Army Research Office **Electronics Division** 



Finanziaria laziale di sviluppo

Filas S.p.A.





Infineon Technologies AG



Office of Naval Research **International Research Office** 



Office of Naval Research



**Intel Corporation** 



**Deutsche** Forschungsgemeinschaft



**Bavarian State** Government

Install Acrobat Reader (Win)

2004 Fourth IEEE Conference on Nanotechnology

17–19 August 2004
Tutorials – 16 August 2004
Technische Universität München
Munich, Germany

Install Acrobat Reader (Mac)

Acrobat
Reader (Unix)

Copyright/Trademarks

## Copyright and Trademarks

© 2004 IEEE. Personal use of this material is permitted. However, permission to reprint/republish this material for advertising or promotional purposes or for creating new collective works for resale or redistribution to servers or lists, or to reuse any copyrighted component of this work in other works must be obtained from the IEEE.

IEEE Catalog Number (CD): 04TH8757C

ISBN: 0-7803-8537-3

Library of Congress: 2004105357

2004 Fourth IEEE Conference on Nanotechnology



Adobe, the Adobe logo, Acrobat and the Acrobat logo are trademarks of Adobe Systems Incorporated or its subsidiaries and may be registered in certain jurisdictions. Macintosh is a registered trademark of Apple Computer, Inc. HP is a registered trademark and HP-UX is a trademark of Hewlett-Packard Company. Motif is a trademark of Open Software Foundation, Inc. Solaris is a registered trademark of Sun Microsystems, Inc., Sun and OpenWindows are trademarks of Sun Microsystems, Inc. SPARC is a registered trademark of SPARC International, Inc. SPARCstation is a registered trademark of SPARC International, Inc., licensed exclusively to Sun Microsystems, Inc. and is based upon an architecture developed by Sun Microsystems, Inc. UNIX is a registered trademark in the United States and other countries, licensed exclusively through X/Open Company, Ltd. Windows is a trademark of Microsoft Corporation. X Window System is a trademark of the Massachusetts Institute of Technology. I386, 486 and Pentium are trademarks of Intel Corporation. All other products or name brands are trademarks of their respective holders.

Conference Details (web link)

Chair Welcome

2004 Fourth IEEE Conference on Nanotechnology

17–19 August 2004
Tutorials – 16 August 2004
Technische Universität München
Munich, Germany

Program Committee

Organizing Committee

Links: IEEE
TUM

#### A message from the General Chair and the Program Chair

On behalf of the organizers, we would like to welcome you to the 2004 Fourth IEEE Conference on Nanotechnology. After successful conferences in Maui, Washington DC and most recently San Francisco, the IEEE Nano Conference has left the United States for the first time this year and arrived in the Old Continent.

It is a great pleasure to welcome you to Munich, a very attractive and dynamic city which, in addition to its profound cultural heritage, is the present day high-tech capital of Germany. It is therefore of great significance for the City, and especially for the Technical University, to host such prestigious event dedicated to a theme with so much impact on future high technology growth. The conference is sponsored by the IEEE Nanotechnology Council, and has received generous financial support from several companies and government agencies. The purpose of the conference is to provide a forum for the discussion and exchange of ideas in various areas of nanoscience and nanotechnology, with the main focus on the engineering aspects of nanotechnology, from nanostructure modeling and fabrication to nanosystems design and realization.

The program of IEEE-Nano 2004 consists of 5 plenary talks, 15 invited presentations, approximately 110 contributed oral presentations and 90 contributed posters (distributed in 2 poster sessions). The Proceedings in this CD-ROM contain all the contributed papers (oral and posters), and the Proceedings Chairpersons and their collaborators are to be praised for such an outstanding achievement. In addition to the invited and contributed presentations, four tutorial short courses are offered on the first day. An exhibition is organized throughout the conference as well. A special panel session on the critical subject of how to teach nanotechnology is organized on Wednesday. A special symposium will take place on Thursday afternoon, dedicated to the applications of Nanotechnology in Medicine. We would like to thank all the members of the Program Committee for their work and effort in putting together a very interesting and high quality program.



We hope that, in addition to the scientific exchange, you will also enjoy the social program, which is as full and attractive as the scientific one. We will start on Monday evening with a welcoming reception hosted by the Bavarian Ministry for Economic Affairs, Infrastructure, Transport and Technology in the fabulous "Residenz" palace Tuesday will feature a classical music concert, and on Wednesday, there will be a conference buffet dinner featuring traditional Bavarian offerings at the Löwenbraukeller, another historical institution of Munich. During both poster sessions, food and wine tasting (this time Italian) will be offered. Finally, on Thursday, a special award lunch will be held, where the best paper of the conference will be awarded. We would like to thank all members of the Organizing Committee and all the staff that have been involved with the preparation of the Conference, and who will be available assist the attendees during the course of the conference.

We thank you all for coming to Munich, and wish you a very interesting, stimulating, and enjoyable time at IEEE NANO 2004. Paolo Lugli, General Chair Stephen M. Goodnick, Program Chair



#### **General Chair**

P. Lugli, TU-München

#### **Program Chair**

S. M. Goodnick, ASU

#### **Program Vice-chairs**

F. Arai, *Nagoya* 

G. Abstreiter, TUM

## Program Committee

2004 Fourth IEEE Conference on Nanotechnology



- J. Appenzeller, IBM (USA)
- Y. Arakawa, Uni. Tokyo (Japan)
- A. Asenov, Uni. Glasgow (UK)
- C. Baatar, ONR (USA)
- S. Bandyopadhyay, VCU (USA)
- V. Baranauskas, Uni. Campinas (Brasil)
- P. Bhattacharya, Uni. Michigan (USA)
- G. Bernstein, Uni. Notre Dame (USA)
- R. Cingolani, Uni. Lecce (Italy)
- S. Coffa, STMicroelectronics (Italy)
- A. Correja, Phantom Network (Spain)
- B. Courtois, TIMA (France)
- R. Cowburn, Uni. Durham (UK)
- H. Craighead, Cornell Uni. (USA)
- A. Csurgay, T.U. Budapest (Hungary)
- D. Deppe, Uni. Texas (USA)
- A. Di Carlo, Uni. Rome "Tor Vergata" (Italy)
- A. Dodabalapur, Uni. Texas (USA)
- J. Fortes, Uni. Florida (USA)
- D. Frank, IBM (USA)
- R. Hatakeyama, Sendai (Japan)
- E. Hu, UCSB (USA)
- C. Jagadish, Austr. National U. (Australia)
- R. Khosla, NSF (USA)
- G. Klimack, Purdue Uni. (USA)
- J. Kotthaus, LMU (Germany)
- F. Kreupl, Infineon (Germany)
- A. Krishnan, DARPA (USA)
- J. Lyding, U.I.U.C. (USA)

- W. Mathis, Uni. Hannover (Germany)
- M. Meyyapan, NASA (USA)
- C. Montemagno, UCLA (USA)
- K.S. Nahm, Chonju Uni. (Korea)
- Y. Nishi, Stanford Uni. (USA)
- H. Ohno, Tohoku Uni. (Japan)
- M. Ohtsu, Tokio I.T. (Japan)
- Y. Park, Samsung (Korea)
- G. Pomerenke, AFSO (USA)
- R.J. Pryputniewicz, WPI (USA)
- J. Randall, Zyvex (USA)
- A. Requicha, U.S.C. (USA)
- M.L. Roukes, Caltech (USA)
- J. Ryan, Oxford Uni. (UK)
- H. Sakaki, Uni. Tokyo (Japan)
- L. Samuleson, Lund (Sweden)
- M. Sitti, Carnagie Mellon (USA)
- R. Tomellini, EU (Belgium)
- A. Toriumi, Uni. Tokyo (Japan)
- O. Wada, Kobe Uni. (Japan)
- R. Waser, Forschungszentrum Juelich (Germany)
- G. Whitesides, Harward Uni. (USA)
- S. Williams, HP (USA)
- J. Wolter, Eindhoven Univ. of Technology (Netherlands)
- D. Woolard, ARO (USA)
- N. Xi, Michigan State Uni. (USA)
- E. Yablanovitch, UCLA (USA)
- A. Zweck, DVI-TZ (Germany)

#### **US Liaison**

C. Lau, ODUSD (USA)

#### **Greater Asia Liaison**

P. Wu, NCT (Taiwan)

#### **European Liaison**

J. Wolter, Eindhoven University of Technology (Netherlands)

#### **Conference Treasurer**

P. Vogl, *TUM* (*Germany*)

#### **Short Courses Chair**

(Italy)

**Student Activity Chairs** 

M. Meyyappan, NASA Ames Research Center (USA)

D. Janes, *Purdue University* (*USA*)

E. Molinari, *University of Modena* 

#### **Publication Chairs**

A. Di Carlo, *University of Rome "Tor* Vergata" (Italy) W. Porod, *University of Notre Dame* (USA)

#### **Local Arrangement Chair**

G. Scarpa, TUM (Germany)

#### Organizing Committee

2004 Fourth IEEE Conference on Nanotechnology



A, B, C, D, E, F, G, H

I, J, K, L, M, N, O

P, Q, R, S, T

U, V, W, X, Y, Z

2004 Fourth IEEE Conference on Nanotechnology

17–19 August 2004
Tutorials – 16 August 2004
Technische Universität München
Munich, Germany

**Tutorials** 

2004 Fourth IEEE Conference on Nanotechnology

17–19 August 2004
Tutorials – 16 August 2004
Technische Universität München
Munich, Germany

Oral Sessions

Poster Sessions 1

Poster Session 2

#### **TUESDAY ORAL SESSIONS:**

TU\_PL: PLENARY SESSION

TU\_1\_1: CARBON NANOTUBES 1

TU\_1\_2: NANOMATERIALS

TU\_1\_3: NANOROBOTICS

TU\_2\_1: NANOELECTRONICS 1

TU\_2\_2: NANOFABRICATION 1

TU\_2\_3: NANOPHOTONICS 1

TU\_3\_1: NANOELECTRONICS 2

TU\_3\_2: NANOSTRUCTURES 1

TU\_3\_3: TEACHING NANOTECHNOLOGY

#### WEDNESDAY ORAL SESSIONS:

WE PL: PLENARY SESSION

WE\_1\_1: MOLECULAR ELECTRONICS

WE\_1\_2: SPINTRONICS

WE\_1\_3: NANOSENSORS

WE\_2\_1: NANOCIRCUITS

WE\_2\_2: NANOSTRUCTURES 2

WE\_2\_3: NANOFABRICATION 2

WE\_3\_1: NANOPHOTONICS 2

WE\_3\_2: NANOELECTRONICS 3



#### WE\_3\_3: NANOBIOELECTRONICS

#### THURSDAY ORAL SESSIONS:

TH\_1\_1: NANOMECHANICS

TH\_1\_2: "DURINT" PROJECT - NANOELECTRONICS

TH\_1\_3: NANOFABRICATION 3

TH\_2\_1: NANOBIOELECTRONICS 2

TH\_2\_2: "DURINT" PROJECT - NANOCIRCUITS

TH\_2\_3: NANOELECTRONICS 4

TH\_3\_1: (Late news papers)

TH\_3\_2: NANOMANIPULATION

TH\_SP: SYMPOSIUM ON "Applications of Nanotechnology in

Medicine"

#### **MONDAY AUG. 16th**

9.00-12.30 Tutorial short course I : Carbon Nanotubes (M. Meyyapan, NASA)

9.00-12.30 Tutorial short course II : Nanoelectronics (S.M. Goodnick, ASU)

14.00-17.30 Tutorial short course III: Molecular Electronics (P. Lugli, TUM; A. Di Carlo, Rome "Tor Vergata")

14.00-17.30 Tutorial short course IV : Bioelectronics (B. Wolf and coworkers, TUM)

19.00 Welcoming Reception at "Residenz"

#### **TUESDAY AUG. 17th**

#### 8.45 Opening

9.00-11.00 TU\_PL: PLENARY SESSION (Chair: S. M. Goodnick)

9.00 TU\_PL\_1 Plenary lecture: Nanoelectronic a quantum leap

Klaus von Klitzing (Max-Planck-Institut FKF, Stuttgart, Germany)

**10.00** TU\_PL\_2 Plenary lecture: Benchmarking Nanotechnology for High-Performance and Low-Power Logic Transistor Applications Robert Chau, (Intel Corporation, Portland, OR, USA)

11.00 Coffee break

## 11.30-12.45 SESSION TU1\_1: CARBON NANOTUBES 1 (Chair: G. Abstreiter)

## TU1\_1\_1 Invited talk: Carbon nanotube electronics and opto-electronics

Phaedon Avouris (IBM Research Division, T.J. Watson Research Center, Yorktown Heights, USA)

TU1\_1\_2 Carbon Nanotube Based High Current Transistors, R. Seidel, A.P. Graham, E. Unger, G.S. Duesberg, M. Liebau, W. Steinhoegl, W. Pamler, and F. Kreupl, (Infineon Technologies AG, Corporate Research, 81730 Munich, Germany)

TU1\_1\_3 Simulation of Carbon Nanotube Field-Effect Devices,
L. Latessa<sup>1</sup>, A. Pecchia<sup>1</sup>, A. Di Carlo<sup>1</sup>, G. Scarpa<sup>2</sup>, and P. Lugli<sup>2</sup>, (\*Dept. of Electronic Engineering, University of Rome "Tor Vergata", Rome, Italy, \*2Dept. of Electrical Engineering, Technical University of Munich, Munich, Germany)

#### TU1\_1\_4 Deposition and STM Investigation of Single-Walled Carbon Nanotubes on GaAs(110),

L.B. Ruppalt, P.M. Albrecht, and J.W. Lyding, (Beckman Institute and Dept. of Electrical and Computer Engineering, University of Illinois, Urbana, Champaign 61801, USA)

#### 11.30-12.45 SESSION TU1\_2: NANOMATERIALS (Chair: U. Ravaioli)

#### TU1\_2\_1 Two-color Size-Tunable (1100-1600 nm) Quantum Dot Nanocrystal Electroluminescent Devices,

L. Bakueva, G. Konstantatos, L. Levina, E.H. Sargent, (Dept. of Electrical & Computer Engineering, University of Toronto, Toronto M5S 3G4, Canada)

#### TU1\_2\_2 Thermal Conductivity of Si/Ge Quantum Dot Superlattices,

A. Khitun<sup>1</sup> J. Liu<sup>2</sup> and K.L. Wang<sup>1</sup>, (\*Device Research Laboratory, Electrical Engineering Dept., MARCO Focus Center on Functional Engineered Nano Architectonics (FENA), University of California at Los Angeles, California, 90095-1594, USA, \*Dept. of Electrical Engineering, University of California at Riverside, Riverside, CA 92521, USA)

#### TU1\_2\_3 Characterization Approaches of Nanoscale Modified Plastics,

D. Vogel<sup>1</sup>, J. Keller<sup>1</sup>, B. Michel<sup>1</sup>, M. Holst<sup>2</sup>, M. Muzic<sup>2</sup>, (\*Fraunhofer IZM, Micro Materials Center Berlin, Berlin, Gustav-Meyer-Allee 25, D-13355 Berlin, Germany, \*2Robert Bosch GmbH, P.O.B. 11 31, D-71301 Waiblingen, Germany)

## TU1\_2\_4 Highly Thermal Robust Ni-Germanosilicide Utilizing NiPt/Co/TiN Tri-layer for CMOS Application,

J.-G. Yun<sup>1</sup>, S.-Y. Oh<sup>1</sup>, H.-H. Ji<sup>1</sup>, B.-F. Huang<sup>1</sup>, S.-H. Park<sup>2</sup>, H.-S. Lee<sup>2</sup>, D.-B. Kim<sup>2</sup>, U.-S. Kim<sup>2</sup>, H.-S. Cha<sup>2</sup>, S.-B. Hu<sup>2</sup>, J.-G. Lee<sup>2</sup>, and

H.-D. Lee<sup>1</sup>, (¹Dept. of Electronics Engineering, Chungnam National University, Yuseong-gu, Daejeon 305-764, Korea, ²System IC R&D Division, Hynix Semiconductor Inc., Hungduk-Gu, Chongju 361-725, Korea)

## TU1\_2\_5 Nanoscale Materials Modification Via Low-Energy Reactive Plasmas,

P.A. Kraus, T.C. Chua, C.S. Olsen, T.M. Bauer\*, (Front End Products Group, Applied Materials, Sunnyvale, CA, USA, \*Sandia National Laboratories, Albuquerque, NM, USA)



## 11.30-12.45 SESSION TU1\_3: NANOROBOTICS (Chair: T. Fukuda\*)

TU1\_3\_1 Carbon Nanotube-Tipped Microcantilever Arrays for Imaging, Testing, and 3D Nanomanipulation: Design and Control,

E. Lee, and M.J. Chung, (Korea Advanced Institute of Science and Technology, Daejeon, 305-701, South Korea)

## TU1\_3\_2 Dynamic Modes of Nano-Particle Motion During Nanoprobe Based Manipulation,

A. Tafazzoli and M. Sitti, (Dept. of Mechanical Eng., Carnegie Mellon University, Pittsburgh, PA 15213, USA)

## TU1\_3\_3 Nonlinear Dynamics of a Micro-Cantilever in Close Proximity to a Surface,

F. Jamitzky<sup>1,2</sup>, M. Stark<sup>3,4</sup>, W. Bunk<sup>2</sup>, W.M. Heckl<sup>1</sup>, R.W. Stark<sup>1</sup>, (<sup>1</sup>Center for Nanoscience and Ludwig-Maximilians-Universität, 80333 Munich, Germany, <sup>2</sup>Center for Interdisciplinary Plasma Science and Max-Planck-Insitut für Extraterrestrische Physik, 85748 Garching, Germany, <sup>3</sup>Laboratoire Spectrométrie Physique, UJF/CNRS, 38402 St Martin d'Hères, France, <sup>4</sup>LEPES (CNRS), 38042 Grenoble, France)

#### TU1\_3\_4 Invited talk: Perspective of Nanotube Sensors and Nanotube Actuators

Toshio Fukuda, Fumihito Arai, Lixin Dong, and Yoshiaki Imaizumi (Department of Micro/Nano System Engineering, Nagoya University, Nagoya, Japan)

## 14.30-16.00 SESSION TU2\_1: NANOELECTRONICS 1 (Chair: G. Klimeck\*)

#### TU2\_1\_1 Invited talk: Quantum devices in semiconductor nanowires

Lars Samuelson (Lund University, Solid State Physics/the Nanometer Structure Consortium LUND, Sweden)

#### TU2\_1\_2 STTM - Promising Nanoelectronic DRAM Device,

S.J. Baik, Z. Huo, S.-H. Lim, I.-S. Yeo, S. Choi, U.-I. Chung, and J.

T. Moon, (Process Development Team, Semiconductor R&D Center, Samsung Electronics Co., LTD. San#24 Nongseo-Ri, Giheung-Eup, Yongin-City, Gyeonggi-Do, Korea 449-711)

## TU2\_1\_3 Fabrication of Single-Electron Transistors Based on Proximity Effects of Electron-Beam Lithography,

S.-F. Hu<sup>1</sup>, Y.-P. Fang<sup>2</sup>, Y.-C. Chou<sup>2</sup> and G.-J. Hwang<sup>3</sup>, (National Nano Device Laboratoriesm, Hsinchu 30050, Taiwan, R.O.C., Dept. of Physics, National Tsing Hua University, Hsinchu 30043, Taiwan, R.O.C., Center of Measurement Standards, Industrial Technology Research Institute, Hsinchu 30042, R.O.C.)

#### TU2\_1\_4 Defect Characterization and Yield Analysis of Array-Based Nanoarchitecture,

S. Zhang<sup>1</sup>, M. Choi<sup>1</sup>, and N. Park<sup>2</sup>, (1 Dept. of ECE, University of Missouri-Rolla, Rolla, MO 65409-0040, USA, 2 Dept. of CS, Oklahoma State University, Stillwater, OK 74078, USA)

TU2\_1\_5 Triple High  $\kappa$  Stacks (Al<sub>2</sub>O<sub>3</sub>/HfO<sub>2</sub>/Al<sub>2</sub>O<sub>3</sub>) with High Pressure 10atm) H<sub>2</sub> and D<sub>2</sub> Annealing for SONOS Type Flash Memory Device Applications,

S. Jeon, S. Choi\*, H. Park\*, H. Hwang\*, J.H. Han, H. Chae, S.D. Chae, J.H. Kim, M.K. Kim, Y.S. Jeong, Y. Park, S. Seo, J.W. Lee, and

C.W. Kim, (M.D. lab, Samsung Advanced Institute of Technology, San 14 Nongseo-ri, Kihung-up, Yongin-si, Kyungki-do, Korea, Dept. of Materials Science & Engineering, Kwangju Institute of Science & Technology, Gwangju, 500-712, Korea)

## 14.30-16.00 SESSION TU2\_2: NANOFABRICATION 1 (Chair: R.J. Pryputniewicz)

#### TU2\_2\_1 Design and Simulation of Magnetically Controlled Nanoscale Assembly,

G. Friedman, B. Yellen and I. Tsukerman\*, (Drexel University, Electrical and Computer Engineering Dept., Philadelphia, PA 19104, USA, \*Dept. of Electrical & Computer Engineering, The University of Akron, OH 44325, USA)

#### TU2\_2\_2 Dip Pen Nanolithography™ and its Potential for Nanoelectronics,

B. Rosner, N. Amro, S. Disawal, L. Demers, H. Zhang, J. Rendlen, T. Duenas, R. Shile, J. Fragala, R. Elghanian, (NanoInk Inc., Chicago, IL 60607, USA; NanoInk Inc., Campbell, CA 95008, USA)

#### TU2\_2\_3 Fabrication of Embedded Media by Etching of Self-Assembled Mask,

L.K. Verma and V. Ng, (Information Storage Materials Laboratory, Dept. of Electrical and Computer Engineering, National University of Singapore, 4 Engineering Drive 3, Singapore 117576)

## TU2\_2\_4 Fabrication of Magnetic Nanostructures Using KrF Lithography,

N. Singh<sup>1,2</sup>, Goolaup S.<sup>2</sup> and A.O. Adeyeye<sup>2</sup>, (<sup>1</sup>Institute of Microelectronics, 11 Science Park Road, Singapore Science Park II, Singapore -117685, <sup>2</sup>Dept. of Electrical and Computer Engineering, National University of Singapore, 4 Engineering drive 3, Singapore-117576)

## TU2\_2\_5 Scanning Tunneling Microscopy Using Dynamic Laser Heating,

J. Ballard, D. Shi, E. Carmichael, S. Pappu, J. Lyding, and M. Gruebele, (Beckman Institute of Advanced Science and Technology, University of Illinois, Urbana, IL, 61801, USA)

## TU2\_2\_6 Self-Assembled Monolayer Resists for Electron Beam Lithography,

S.O. Koswatta, A.D. Scott, S. Bhattacharya, and D.B. Janes, (Dept. of Electrical and Computer Engineering, Purdue University, West Lafayette, IN 47906, USA)



## 14.30-16.00 SESSION TU2\_3: NANOPHOTONICS 1 (Chair: Y. Arakawa\*)

TU2\_3\_1 A Basic Architecture for a Multistate Memory System Using Nano Antennas,

Lakshmanan.V.H, Gayathri.S, (Velammal Engineering College, Chennai-600082, Tamil Nadu, India)

TU2\_3\_2 Comparing the Transmission Through Ellipse and Double-Hole Nano-Photonic Arrays in Gold Films,

R. Gordon<sup>1</sup>, B. Leathem<sup>2</sup>, P.D. Popescu<sup>1</sup>, K.L. Kavanagh<sup>2</sup> and A.G. Brolo<sup>3</sup>, Apart of Floring and Computer Engineering, University of Violence 2 Dant of Physics, Simon

 $\mathsf{Brol}\,\mathcal{O}^3$ , (\*Dept. of Electrical and Computer Engineering, University of Victoria, \*Dept. of Physics, Simon Fraser University, \*Dept. of Chemistry, University of Victoria)

#### TU2\_3\_3 Light Emission at 1530 nm from Mixture of Er<sub>2</sub>O<sub>3</sub> and P<sub>2</sub>O<sub>5</sub> Nanoparticles on Silicon,

K.-J. Sun, Y.-S. Su, C.-F. Lin\*, (Graduate Institute of Electro-Optical Engineering, National Taiwan University, No.1, Sec. 4, Roosevelt Road, Taipei, 106, Taiwan, R.O.C, \*also with Graduate BInstitute of Electronics Engineering, and Dept. of Electrical Engineering)

## TU2\_3\_4 Quantum Confinement Observed in Ultrafine ZnO and ZnO/Zn<sub>0.8</sub>Mg<sub>0.2</sub>O Coaxial Nanorod Heterostructures,

W.I. Park<sup>1</sup>, S.J. An<sup>1</sup>, G.-C. Yi<sup>1</sup>, and M. Kim<sup>2</sup>, <sup>(1</sup>Dept. of Materials Science and Engineering, Pohang University of Science and Technology, (POSTECH), Pohang 790-784, Korea, <sup>2</sup>Samsung Advanced Institute of Science and Technology, P. O. Box 111, Suwon 440-600, Korea)

TU2\_3\_5 Invited talk: Photonic switching in InAs/InP quantum dots J.E.M. Haverkort, R. Prasanth, S. Dilna, E.W. Bogaart, J.J.G.M. van der Tol, E.A. Patent, G. Zhao, Q. Gong, P.J. van Veldhoven, R. Nötzel and J.H. Wolter, (COBRA Inter-University Research Institute, Eindhoven University of Technology, Physics Dept., Eindhoven, The Netherlands)

16.00-16.30 Coffee break



## 16.30-18.00 SESSION TU3\_1: NANOELECTRONICS 2 (Chair: D. K. Ferry)

## TU3\_1\_1 Invited talk: Coherent Transport in SWCNTs with Spin-Orbit Coupling

Ahmet Ali Yanik, Prabhakar Srivastava, Gerhard Klimeck and Supriyo Datta (Purdue University, Purdue, IN, USA)

## TU3\_1\_2 Ballistic Transport in Strained-Si Cavities: Experiment and Theory,

G. Scappucci<sup>1</sup>, L. Di Gaspare<sup>1</sup>, A. Notargiacomo<sup>1</sup>, F. Evangelisti<sup>1</sup>, E. Giovine<sup>2</sup>, R. Leoni<sup>2</sup>, V. Piazza<sup>3</sup>, P. Pingue<sup>3</sup>, F. Beltram<sup>3</sup>, M. Pala<sup>4</sup>, G. Curatola<sup>4</sup>, and G. Iannaccone<sup>4,5</sup>, (\*Unità INFM, Dipartimento di Fisica "E. Amaldi", Università di Roma TRE, V. Vasca Navale 84, 00146 Roma, Italy, \*Istituto di Fotonica e Nanotecnologie, IFN-CNR, V. Cineto Romano 42, 00156, Roma, Italy, \*NEST-INFM and Scuola Normale Superiore, Via della Faggiola 19, I-56126 Pisa, Italy, \*Dipartimento di Ingegneria dell'Informazione, Università degli Studi di Pisa and \*IEIIT-CNR, V. Caruso, 56122 Pisa, Italy)

## TU3\_1\_3 Very High Performance 50 nm T-gate III-V HEMTs Enabled by Robust Nanofabrication Technologies,

I. Thayne, X. Cao, D. Moran, E. Boyd, K. Elgaid, H. McLelland, M. Holland, S. Thoms, C. Stanley, (Nanoelectronics Research Centre, Dept. of Electronics and Electrical Engineering, University of Glasgow, Glasgow G12 8LT, Scotland, UK)

TU3\_1\_4 Ballistic GaInAs/AlInAs Devices Technology and

#### Characterization at Room Temperature,

J.S. Galloo<sup>1</sup>, Y. Roelens<sup>1</sup>, S. Bollaert<sup>1</sup>, E. Pichonat<sup>1</sup>, X. Wallart<sup>1</sup>, A. Cappy<sup>1</sup>, J. Mateos<sup>2</sup>, T. Gonzales<sup>2</sup>, (\*IEMN-UMR CNRS 8520, Villeneuve d'Ascq, BP 69, 59652, France, \*2Universidad de Salamanca, Plaza de la Merced s/n, 37008 Salamanca, Spain)

#### TU3\_1\_5 Why is the Spin Field Effect Transistor Elusive?

S. Pramanik<sup>1</sup>, S. Bandyopadhyay<sup>1</sup>, and M. Cahay<sup>2</sup>, (\*Dept. of Electrical Engineering, Virginia Commonwealth University, Richmond, VA 23284, USA, \*Dept. of Electrical and Computer Engineering and Computer Science, University of Cincinnati, Cincinnati, OH 45221, USA)

## 16.30-18.00 SESSION TU3\_2: NANOSTRUCTURES 1 (Chair: Y. Park)

#### TU3\_2\_1 Effect of Topology on Coherent Transport Through Nanotube Junctions,

A. Marchi<sup>1,</sup> A. Bertoni<sup>2</sup>, S. Reggiani<sup>1</sup>, and M. Rudan<sup>1</sup>, (Advanced Research Center on Electronic Systems (ARCES) and Dept. of Electronics (DEIS), University of Bologna, Italy, INFM-S3 Research Center, Modena, Italy and ARCES, Bologna, Italy)

## TU3\_2\_2 High Frequency Characterization for the Single-Walled Carbon Nanotubes Using S-parameter,

M. Zhang, X. Huo, Q. Liang\*, Z.K. Tang\* and P.C.H. Chan, (Dept. of Electrical and Electronic Engineering and \*Dept. of Physics, Hong Kong University of Science and Technology, Hong Kong, China)

### TU3\_2\_3 Carbon Nanotube-Based Membranes: A Platform for Studying Nanofluidics,

J.K. Holt, H.G. Park, A. Noy, T. Huser, D. Eaglesham, and O. Bakajin, (Chemistry and Materials Science Directorate, Lawrence Livermore National Laboratory, Livermore, CA 94551, USA)

TU3\_2\_4 Metalloprotein-Based Field-Effect Transistor: A Prototype, G. Maruccio<sup>1</sup>, P. Visconti, A. Biasco, A. Bramanti, E. D'Amone, R. Cingolani, and R. Rinaldi, (National Nanotechnology Laboratory of INFM, University of Lecce, Via per Arnesano, 73100 Lecce, Italy, <sup>1</sup>also with Dept. of Physics, University of Lecce)

## TU3\_2\_5 Theoretical Investigation of Metal-Molecule Interface with Terminal Group,

P. Bai<sup>1</sup>, E. Li<sup>1</sup>, S. Yang<sup>1</sup>, P.A. Collier<sup>2</sup>, (\*Institute of High Performance Computing, Singapore 117528, \*Singapore Institute of Manufacturing Technology, Singapore 638075)

TU3\_2\_6 Schottky Barrier Behavior of Metallic Multi-wall Carbon Nanotube on-Metal Systems,

Quoc Ngo<sup>1,2</sup>, Shoba Krishnan<sup>1</sup>, Alexis Stimpfle<sup>1</sup>, M. Meyyappan<sup>2</sup>, and Cary Y. Yang<sup>1</sup> (<sup>1</sup>Center for Nanostructures, Santa Clara University, Santa Clara, California, USA, <sup>2</sup>Center for Nanotechnology, NASA Ames Research Center, Moffett Field, California, USA)



16.30-18.00 SESSION TU3\_3 TEACHING NANOTECHNOLOGY (Chair: A. Csurgay)

18.15-19.30 POSTER SESSION I (see below)



#### **WEDNESDAY AUG. 18th**

8.45-10.45 WE\_PL: PLENARY SESSION

(Chair: M. Meyyapan)

WE\_PL\_1 8.45 Plenary speaker: Technology and Application Trends in Nano-Electronics
Christoph Kutter (Infineon Technologies AG, Corporate Research, München, Germany)

WE\_PL\_2 9. 45 Plenary speaker: Title to be announced

Angela Belcher (Department of Materials Science and Engineering, Massachusetts Institute of Technology, Cambridge, MA, USA)

10.45 Coffee break



## 10.15-12.45 SESSION WE1\_1: MOLECULAR ELECTRONICS (Chair: A. Di Carlo)

#### WE1\_1\_1 Invited talk: Transport and electrostatics in metallic carbon nanotubes

M. P. Anantram, A. Svizhenko and T. R. Govindan (Center for Nanotechnology, NASA Ames Research Center, Moffett Field, CA, USA)

#### WE1\_1\_2 Measurement of I-V Characteristic of Organic Molecules Using Step Junction,

K. Lee, J. Choi, and D.B. Janes, (School of Electrical and Computer Engineering, Purdue University, West Lafayette, IN 47907, USA)

#### WE1\_1\_3 Conductance Investigations of Stretched Molecules,

G. Speyer, R. Akis, and D.K. Ferry, (Dept. of Electrical Engineering and Center for Solid State Electronics Research, Arizona State University, Tempe, AZ 85287, USA)

## WE1\_1\_4 Conductance Modulation in Molecular Devices via Field-Induced Conformational Change,

M. Girlanda<sup>1</sup>, I. Cacelli<sup>1</sup>, A. Ferretti<sup>2</sup>, and M. Macucci<sup>3</sup>, (\*Dipartimento di Chimica e Chimica Industriale, Università degli Studi di Pisa, Via Risorgimento 35, I-56122 Pisa, Italy, <sup>2</sup>IPCF-CNR, Pisa, Italy, <sup>3</sup>Dipartimento di Ingegneria dell'Informazione, Università degli Studi di Pisa, Via Caruso, I-56122 Pisa, Italy)

WE1\_1\_5 Transistor Effects and in situ STM of Redox Molecules at Room Temperature,

T. Albrecht<sup>1</sup>, A. Guckian<sup>2</sup>, J. Ulstrup<sup>1</sup>, H. Vos<sup>2</sup>, (<sup>1</sup>Technical University of Denmark (DTU), Dept. of Chemistry, Dk-2800 Lyngby, <sup>2</sup>Dublin City University (DCU), School of Chemical Sciences, Dublin 9, Ireland)



## 10.15-12.45 SESSION WE1\_2: SPINTRONICS (Chair: S. Bandyopadhyay)

#### WE1\_2\_1 Application of Mesoscopic Magnetic Rings for Logic Devices.

A. Imre<sup>1</sup>, L. Zhou<sup>1</sup>, A. Orlov<sup>1</sup>, G. Csaba<sup>2</sup>, G. H. Bernstein<sup>1</sup>, W. Porod<sup>1</sup>, and V. Metlushko<sup>3</sup>, (\*Center for Nano Science and Technology, Dept. of Electrical Engineering, University of Notre Dame, Notre Dame, IN 46556, USA, \*Institute for Nanoelectronics, TU Munich, Munich, Germany, \*3University of Illinois at Chicago, Chicago, IL 60607, USA)

#### WE1\_2\_2 Spin Polarized Injectors for Organic Light Emitting Diodes.

E. Arisi<sup>1</sup>, I. Bergenti<sup>1</sup>, V. Dediu<sup>1</sup>, T. Mertelj<sup>2</sup>, M. Murgia<sup>1</sup>, A. Riminucci<sup>1</sup>, G. Ruani<sup>1</sup>, and C. Taliani<sup>1</sup>, (<sup>1</sup> Istituto per lo studio dei Materiali Nanostrutturati, CNR, Bologna, Italy, <sup>2</sup> Dept. of Mathematics and Physics, University of Ljubjana, 1000 Ljubjana, Slovenia)

## WE1\_2\_3 Invited talk: Ferromagnetic semiconductors for nanospintronics

Tomasz Dietl (Institute of Physics, Polish Academy of Sciences and ERATO Semiconductor Spintronics JST Project, Warszawa, Poland)

## WE1\_2\_4 Invited talk: Electrical Magnetization Reversal in Ferromagnetic Semiconductor Structures

Hideo Ohno (Laboratory for Nanoelectronics and Spintronics Research Institute of Electrical Communication Tohoku University, JAPAN ERATO Semiconductor Spintronics Project, JST, Japan)

## 10.15-12.45 SESSION WE1\_3: NANOSENSORS (Chair: B. Courtois)

#### WE1\_3\_1 Self-Assembled Silicon Nano-Bridges as an Enabler for Nano-Sensors,

T.I. Kamins, M.S. Islam, S. Sharma, and R.S. Williams, *Quantum Science Research, Hewlett-Packard Laboratories, Palo Alto, CA 94304, USA*)

#### WE1\_3\_2 Ultra-Small Site Temperature Sensing by Carbon Nanotube Thermal Probes,

F. Arai, C. Ng, P. Liu, L. Dong, Y. Imaizumi, K. Maeda, H. Maruyama, A. Ichikawa and T. Fukuda, (Dept. of Micro System Engineering, Nagoya University, Nagoya, Aichi, 464-8603, Japan)

#### WE1\_3\_3 Piezoresistive Behaviour of Single Wall Carbon Nanotubes.

P. Regoliosi<sup>1</sup>, A. Reale<sup>1</sup>, A. Di Carlo<sup>1</sup>, S. Orlanducci<sup>2</sup>, M.L. Terranova<sup>2</sup>, P. Lugli<sup>3</sup> (\*Dept. of Electronic Engineering, Univ. of Rome Tor Vergata, Rome, 00133 Italy, \*Dept. of Science and Chemical Technology, Univ. of Rome Tor Vergata, Rome, 00133 Italy and INFM \*Lehrstuhl für Nanoelektronik, TU München, Arcisstrasse 21 München, D-80333 Germany)

#### WE1\_3\_4 Field Emission of Telescoping Multi-Walled Carbon Nanotubes,

Lixin Dong <sup>1,2</sup>, Fumihito Arai <sup>1</sup>, Toshio Fukuda <sup>1</sup>, and Bradley J. Nelson <sup>3</sup> (1 Nagoya University, Furo-cho, Chikusa-ku, Nagoya 464-8603, Japan, <sup>2</sup> Currently ETH-

Zurich, <sup>3</sup> Swiss Federal Institute of Technology (ETH), Zurich, Switzerland)

## WE1\_3\_5 Estimation of the Transfer Function of a Microcantilever Used in Atomic Force Microscopy,

M. Stark<sup>1</sup>, R. Guckenberger<sup>1</sup>, A. Stemmer<sup>2</sup>, R. W. Stark<sup>2,3</sup>, (Max-Planck-Insitut für Biochemie, 82152 Martinsried, Germany, Swiss Federal Institute of Technology Zurich, ETH Center CLA, 8092 Zurich, Switzerland, Center for Nanoscience and Ludwig-Maximilians-Universität, 80333 Munich, Germany)

## WE1\_3\_6 Ultra-Low-Power Polymer Thin Film Encapsulated Carbon Nanotube Thermal Sensors,

C.K.M. Fung and W.J. Li, (Centre for Micro and Nano Systems, The Chinese University of Hong Kong, Hong Kong SAR)



## 14.30-16.00 SESSION WE2\_1: NANOCIRCUITS (Chair: W. Mathis)

### WE2\_1\_1 Invited talk: Circuit Models for Physically-Coupled Nanoelectronic Device Architectures

Wolfgang Porod and Arpad Csurgay (Center for Nano Science and Technology, University of Notre Dame, Notre Dame, IN, USA)

## WE2\_1\_2 Cellular Nonlinear Network Based on Semiconductor Tunneling Structure with a Self-Assembled Quantum Dot Layer,

A. Khitun and K.L. Wang, (Device Research Laboratory, Electrical Engineering Dept., MARCO Focus Center on Functional Engineered Nano Architectonics (FENA), University of California at Los Angeles, Los Angeles, California, 90095-1594, USA)

## WE2\_1\_3 Cellular Neural/Nonlinear Networks Using Resonant Tunneling Diode,

S.-R. Li, P. Mazumder and L.O. Chua, (Dept. of EECS, The University of Michigan, Ann Arbor, MI, 48109, USA)

## WE2\_1\_4 Dynamic Sparing and Error Correction Techniques for Fault Tolerance in Nanoscale Memory Structures,

C.M. Jeffery, A. Basagalar, and R.J.O. Figueiredo, (University of Florida, Gainesville, FL, 32611, USA)

WE2\_1\_5 Carbon Nanotubes for Quantum-Dot Cellular Automata

### Clocking,

S.E. Frost<sup>1</sup>, T.J. Dysart<sup>1</sup>, P.M. Kogge<sup>1</sup> and C.S. Lent<sup>2</sup>, (\*Dept. of Computer Science and Engineering, \*Dept. of Electrical Engineering, University of Notre Dame, Notre Dame, IN 46556, USA)



## 14.30-16.00 SESSION WE2\_2: NANOSTRUCTURES 2 (Chair: M. Sitti\*)

WE2\_2\_1 Use of an Organic Template Structure for the Manipulation of Nano-Scale Objects,

S.J.H. Griessl, M. Lackinger, and W.M. Heckl, (Dept. für Geo- und Umweltwissenschaften, Ludwig Maximilians Universität München, Theresienstr. 41, 80333 München)

WE2\_2\_2 Growth of ZnSe Nanowires by Molecular Beam Epitaxy, A. Colli<sup>1</sup>, F. Martelli<sup>2</sup>, S. Rubini<sup>2</sup>, C. Ducati<sup>3</sup>, S. Hofmann<sup>1</sup>, A. C. Ferrari<sup>1</sup>, J. Robertson<sup>1</sup>, and A. Franciosi<sup>2,4</sup>, (\*Dept. of Engineering, University of Cambridge, Cambridge CB2 1PZ, UK., \*Laboratorio Nazionale TASC-INFM, Area Science Park, 34012 Trieste, Italy, \*Dept. of Materials Science and Metallurgy, University of Cambridge, Cambridge, UK, \*Dipartimento di Fisica, Universita' di Trieste, 34127 Trieste, Italy)

### WE2\_2\_3 Platinum/Erbium Disilicide Nanowire Arrays on Si(001),

R. Ragan, S. Kim, D.A.A. Ohlberg, and

R. Stanley Williams, (Hewlett-Packard Laboratories, Quantum Science Research, Palo Alto, CA, 94304, USA)

## WE2\_2\_4 Measurements with an Atomic Force Microscope Using a Long Travel Nanopositioning Machine,

N. Hofmann, T. Hausotte, G. Jäger and E. Manske, (Technische Universität Ilmenau Institute of Measurement- and Sensor-Technology, 98693 Ilmenau)

- WE2\_2\_5 Fracture Mechanical Characterization of Micro- and Nano-Filled Polymers by a Combined Experimental and Simulative Procedure,
- B. Wunderle<sup>1</sup>, D. Dermitzaki<sup>2</sup>, J. Keller<sup>1</sup>, Di. Vogel<sup>1</sup>, B. Michel<sup>1</sup>, (Fraunhofer Institute for Reliability and Microintegration (IZM), Dept. Mechanical Reliability and Micro Materials, Gustav-Meyer-Allee 25, D-13355 Berlin, Germany, <sup>2</sup>Heriot-Watt University Edinburgh, School of Engineering and Physical Sciences, Ricarton Campus, EH14 4AS, UK)

WE2\_2\_6 Long-Range Ordered Self-Assembled InAs Quantum Dots on (110) GaAs Grown with Molecular Beam Epitaxy, D. Schuh, J. Bauer, R. Schulz, E. Uccelli, F. Hofbauer, A. Kress, J.J. Finley, and G. Abstreiter, (Walter Schottky Institut, Technische Universität München, Am

Coulombwall 3, D-85748 Garching, Germany)

## 14.30-16.00 SESSION WE2\_3: NANOFABRICATION 2 (Chair: G.H. Berstein\*)

WE2\_3\_1 Ni-P-CNTs Nanocomposite Film for MEMS Applications, G.-R. Shen<sup>1</sup>, L.-N. Tsai<sup>2</sup>, T.Y. Chao<sup>1</sup>, Y.-T. Cheng<sup>1</sup>, T. K. Lin<sup>3</sup>, W. Hsu<sup>2</sup>, (\*Microsystems Integration Laboratory, Dept. of Electronics Engineering, \*Dept. of Mechanical Engineering, National Chiao Tung University, 1001 Ta Hsueh Road, Hsinchu, Taiwan, 300, ROC, \*Dept. of Chemical Engineering, Hwa Hsia College of Technology & Commerce.)

WE2\_3\_2 Pure Metal Deposit Using Multi-Walled Carbon Nanotubes Decorated with Ruthenium Dioxide Super-Nanoparticles, F. Arai<sup>1</sup>, P. Liu<sup>1</sup>, L. Dong<sup>1</sup>, T. Fukuda<sup>1</sup>, T. Noguchi<sup>2</sup> and K. Tatenuma<sup>2</sup>, (\*Nagoya University, Furo-cho, Chikusa-ku, Nagoya 464-8603, Japan, \*2KAKEN Inc., Horicho, Mito, Ibaraki 310-0903, Japan)

WE2\_3\_3 Nanoimprint - A Tool for Realizing Nano-Bio Research,
P. Carlberg<sup>1</sup>, F. Johansson<sup>1</sup>, T. Mårtensson<sup>1</sup>, R. Bunk<sup>1</sup>, M. Beck<sup>1</sup>, F.
Persson<sup>1</sup>, M. Borgström<sup>1</sup>, S.G. Nilsson<sup>1</sup>, B. Heidari<sup>4</sup>, M. Grazcyk<sup>1</sup>, I.
Maximov<sup>1</sup>, E.-L. Sarwe<sup>1</sup>, T.G.I. Ling<sup>1</sup>, A. Månsson<sup>3</sup>, M. Kanje<sup>2</sup>, W.
Seifert<sup>1</sup>, L. Samuelson<sup>1</sup>, L Montelius<sup>1</sup>, (\*Dept. Solid State Physics & The Nanometer Consortium, Lund University, Sweden, \*Dept. of Cell and Organism Biology, Lund University, Sweden, \*Dept. of Chemistry and Biomedical Sciences, University of Kalmar, Sweden.)

WE2\_3\_4 Electron Beam Lithography and Liftoff of Molecules and DNA Rafts,

G.H. Bernstein, W. Hu, Q. Hang, K. Sarveswaran\*, and M. Lieberman\*, (Dept. of Electrical Engineering and \*Dept. of Chemistry and Biochemistry, University of Notre Dame, Notre Dame, IN 46556, USA)

# WE2\_3\_5 Invited talk: Laser Assisted Direct Imprint and Guided Self-Assembly – Enabling Engines for Nanotechnology

S. Chou (Department of Electrical Engineering, Princeton University, USA)

16.00-16.30 Coffee break



## 16.30-17.30 SESSION WE3\_1: NANOPHOTONICS 2 (Chair: J. Wolter)

## WE3\_1\_1 Invited talk: Progress in Quantum dots for future nano-photonic devices

Yasuhiko Arakawa (RCAST and IIS, University of Tokyo, Tokyo, Japan)

WE3\_1\_2 Modeling Quantum Dots in Conventional and Annular III-V Micro-Pillar Micro-Cavities for Single-Photon Sources,

Y.-L.D. Ho, M.J. Cryan, I.J. Craddock, C.J. Railton, and J.G. Rarity, (Centre for Communications Research, Dept. of Electrical and Electronic Engineering, University of Bristol, Queen's Building, University Walk, Bristol, BS8 1TR, United Kingdom)

WE3\_1\_3 Imprint Lithography as a Tool for the Fabrication of Organic-Inorganic Vertical Microcavities,

M. De Vittorio, M.T. Todaro, M. Mazzeo, L. Martiradonna, T. Stomeo, M. Anni, R. Cingolani, and G. Gigli, (NNL-INFM, Dipartimento di Ingegneria dell'Innovazione, Università di Lecce, Via Arnesano, Lecce-73100 Italy)

## 16.30-17.30 SESSION WE3\_2: NANOELECTRONICS 3 (Chair: A. Asenov)

## WE3\_2\_1 Robustness of Readout Devices for Si-Based Quantum Computing,

K.H. Lee<sup>1</sup>, A.D. Greentree<sup>1,2</sup>, V. Chan<sup>1</sup>, T.M. Buehler<sup>1</sup>, R. Brenner<sup>1</sup>, A.S. Dzurak<sup>1</sup>, A.R. Hamilton<sup>1</sup> and R.G. Clark<sup>1</sup>, (\*Centre for Quantum Computer Technology, Schools of Physics and Electrical Engineering, University of New South Wales, NSW 2052, Australia, \*Centre for Quantum Computer Technology, School of Physics, University of Melbourne, VIC 3010, Australia)

## WE3\_2\_2 On the Modeling of Semiconductor Quantum Effects for Circuit Simulation,

F. Felgenhauer, S. Fabel, and W. Mathis, (University of Hannover, Electro Magnetic Theory Group of the Institute of Electromagnetism Theory and Microwave Technique, Appelstr. 9A, 30167 Hannover, Germany)

## WE3\_2\_3 Split Current Quantum Cellular Automata: Device and Logic Gates,

K. Walus, R.A. Budiman, M. Mazur, G.A. Jullien, and G. Schulhof, (ATIPS Laboratory, Dept. of Electrical and Computer Engineering, University of Calgary, Calgary, Alberta T2N-1N4, Canada)

### WE3\_2\_4 Optical Gain in an Interband-Resonant-Tunneling-Diode,

B. Gelmont<sup>1</sup> and D. Woolard<sup>2</sup>, (\*ECE Dept., the University of Virginia, Charlottesville, VA 22904, USA, \*2U.S. Army Research Laboratory, U.S. Army Research Office, RTP, NC 27709, USA)

## 16.30-17.30 SESSION WE3\_3: NANOBIOELECTRONICS (Chair: C. Ruggiero)

WE3\_3\_1 Surface Modification and Bioconjugation of Colloidal Nanocrystals to Form Building Blocks with Molecular Recognition, R.A. Sperling<sup>1</sup>, T. Pellegrino<sup>2</sup>, S. Kudera<sup>1</sup>, A.M. Javier<sup>1</sup>, L. Manna<sup>3</sup>, and W.J. Parak<sup>1</sup>, (¹center for NanoScience, Ludwig-Maximilians-Universität München, Munich, Germany, ²Dept. of Chemistry and Pharmacology, University of Bari, Italy, ³National Nanotechnology Lab of INFM, Via Arnesano, Lecce, Italy)

### WE3\_3\_2 Brownian Dynamics: Molecular Systems Modeling and Control,

M.A. Lyshevski, (Microsystems and Nanotechnologies, 70 Angels Path, Webster, NY 14580-4400, USA)

## WE3\_3\_3 Invited talk: Biological applications and biocompatibility of nanocrystals

C. Kirchner<sup>1</sup>, T. Pellegrino<sup>1,2</sup>, S. Kudera1, T. Liedl<sup>1</sup>, A.M. Javier<sup>1</sup>, H.E. Gaub<sup>1</sup> and W. Parak<sup>1</sup>, (¹center for Nanoscience, Ludwig-Maximilians Universität, München, Germany, ²Dept. of Chemistry and Pharmacology, University of Bari, Bari, Italy)

17.45-19.15 POSTER SESSION II (see below)

20.00 Conference dinner



#### **THURSDAY AUG. 19th**

## 8.45-10-15 SESSION TH1\_1: NANOMECHANICS (Chair: M. Wybourne)

TH1\_1\_1 Nano-Electromechanical Transistor Operated as a Bi-Polar Current Switch,

R.H. Blick<sup>1</sup> and D.V. Scheible<sup>2</sup>, (\*Electrical & Computer Engineering, University of Wisconsin-Madison, Madison, WI 53706, USA, \*Center for NanoScience, Ludwig-Maximilians-Universität, 80539 München, Germany)

TH1\_1\_2 In-Situ Nanomechanical Studies of Carbon Nanotube Bundles,

P. Jaroenapibal, D.E. Luzzi, and S. Evoy, (Dept. of Materials Science and Engineering, The University of Pennsylvania, Philadelphia, PA 19104, USA)

TH1\_1\_3 Single Molecule Detection and Macromolecular Weighting Using an All-Carbon-Nanotube Nanoelectromechanical Sensor,

C. Roman, F. Ciontu, B. Courtois, (Tima Laboratory, 46. Av. Félix Viallet, Grenoble, 38031, France)

TH1\_1\_4 Novel Buckled Shapes of Free-Standing Mesoscopic Beams,

S.M. Carr, W.E. Lawrence, and M.N. Wybourne, (Dept. of Physics and Astronomy, Dartmouth College, Hanover, NH 03755, USA)

TH1\_1\_5 Invited talk: Nanoelectromechanical Sensors

K.L. Ekinci, 1,2 Y.T. Yang, 2 X.M.H. Huang, 2 C. Callegari, 2 P. Feng and

M.L. Roukes (1) Aerospace and Mechanical Engineering, Boston University, Boston MA, 2) Condensed

Matter Physics, California Institute of Technology, Pasadena CA, USA)



# 8.45-10-15 SESSION TH1\_2: "DURINT" PROJECT - NANOELECTRONICS (Chair: H. Cui)

### TH1\_2\_1 Invited talk: Inelastic Electron Tunneling Spectroscopy of an Alkane SAM

W. Wang, T. Lee, I. Kretzschmar, and M. A. Reed (Departments of Electrical Engineering, Applied Physics, and Physics, Yale University, New Haven, CT, USA)

### TH1\_2\_2 Electronic Structure and Dielectric Behavior of Finite-Length Single-Walled Carbon Nanotubes,

Y. Li, D. Lu, S. Rotkin, K. Schulten and U. Ravaioli, (Beckman Institute for Advanced Science and Technology, University of Illinois at Urbana-Champaign Urbana Illinois 61801, USA)

## TH1\_2\_3 Molecular Elements on Silicon Substrates: Modeling Issues and Device Prospects,

A.W. Ghosh, G.-C. Liang, T. Rakshit, D. Kienle, and S. Datta, (School of Electrical and Computer Engineering, Purdue, University, W. Lafayette, IN 47907, USA)

## TH1\_2\_4 Theoretical Research of Mixed-Valence Transition Metal Complex for Molecular Computing,

Peiji Zhao, Dwight Woolard, and Jorge M. Seminario, (Dept. of ECE, North Carolina State University, USA)

TH1\_2\_5 Fabrication and Electrical Characterization of

### Au/Molecule/GaAs Devices,

S. Lodha and D.B. Janes, (School of Electrical and Computer Engineering, Purdue University, West Lafayette, IN 47907–2035, USA)



## 8.45-10-15 SESSION TH1\_3: NANOFABRICATION 3 (Chair: L. Samelson)

TH1\_3\_1 Simulation of Electrical Characteristics of Surrounding - and Omega - Shaped - Gate Nanowire FinFETs,

C.-S. Tang<sup>1</sup>, S.-M. Yu<sup>1</sup>, H.-M. Chou<sup>1</sup>, J.-W. Lee<sup>2</sup>, and Y. Li<sup>1,2</sup>, (<sup>1</sup>National Chiao Tung University, Hsinchu City, Hsinchu 300, Taiwan, <sup>2</sup>National Nano Device Laboratories, Hsinchu City, Hsinchu 300, Taiwan)

## TH1\_3\_2 Nanoscaled Double Y-Branch Junction Operating as Room Temperature RF to DC Rectifier,

L. Bednarz<sup>1</sup>, Rashmi<sup>1</sup>, B. Hackens<sup>2</sup>, H. Boutry<sup>1</sup>, V. Bayot<sup>1</sup>, and I. Huynen<sup>1</sup>, S.-J. Galloo<sup>2</sup>, Y.Roelens<sup>2</sup>, S. Bollaert<sup>2</sup>, E. Pichonat<sup>2</sup>, and A. Cappy<sup>2</sup>, (,<sup>1</sup> Cermin, UCL, 1348 Louvain-la-Neuve, Belgium, <sup>2</sup>IEMN-UMR CNRS 8520, Villeneuve d:Ascq, PB 69, 59652, France)

### TH1\_3\_3 A Novel Single Electron SRAM Architecture,

S. Mahapatra, A.M. Ionescu, (Electronics Laboratory (LEG), Swiss Federal Institute of Technology Lausanne (EPFL), Switzerland)

## TH1\_3\_4 Silicon Nanocrystals: From Coulomb Blockade to Memory Arrays,

R.F. Steimle, R. Rao, M. Sadd, C. Swift, B. Hradsky, S. Straub, T. Merchant, M. Stoker, C. Parikh, S. Anderson, M. Rossow, J. Yater,

B. Acred, K. Harber, E. Prinz, B.E. White Jr., and R. Muralidhar, *Technology Solutions Organization, Motorola SPS, Austin, TX, 78721, USA)* 

### TH1\_3\_5 Modeling Electronic Behavior of Carbon Nanotube Junction Devices,

Q.W. Shi<sup>1</sup> and J. Chen<sup>2</sup>, (\*Dept. of Physics, University of Science and Technology of China, \*2Division of Engineering, Brown University, RI 20912, USA)

## TH1\_3\_6 Microstructure and Nanoelectronics of Single GaN Nanowire with Well-Defined p-n Junction,

G. Cheng<sup>1</sup>, R. Munden<sup>1</sup>, I. Kretzschmar<sup>1</sup>, A. Sanders<sup>1</sup>, E. Stern<sup>1</sup>, M.A. Reed<sup>1</sup>, M. Moskovits<sup>2</sup>, J. Zhang and Y. Wu<sup>3</sup>, (\*Dept. of Electrical Engineering and Applied Physics, Yale University, P.O. Box 208284, New Haven, CT 06520, USA, \*Dept. of Chemistry & Biochemistry, University of California, Santa Barbara, CA 93106, \*Dept. of Materials, University of California, Santa Barbara, CA 93106, USA)

10.15-10.45 Coffee break



## 10.45-12.15 SESSION TH2\_1: NANOBIOELECTRONICS 2 (Chair: W. M. Heckl\*)

## TH2\_1\_1 Invited talk: Motor Proteins to Engineer a Monorail at the Nanoscale

Henry Hess<sup>1</sup> and Viola Vogel<sup>1,2</sup> (<sup>1</sup>Center of Nanotechnology and Department of Bioengineering, University of Washington, Seattle, Washington 98195, and <sup>2</sup>Department of Materials, Swiss Federal Institute of Technology-ETH, Zürich, Switzerland).

## TH2\_1\_2 Interactive DNA Sequence and Structure Design for DNA Nanotechnology and DNA Computation,

M. Zhang<sup>1</sup>, C.L. Sabharwal<sup>2</sup>, W. Tao<sup>3</sup>, T.-J. Tarn<sup>4</sup>, N. Xi<sup>5</sup>, and G. Li<sup>5</sup>, (<sup>1</sup>Life Sciences and Chemical Analysis Division, Agilent Technologies, CA, USA, <sup>2</sup>Dept. of Computer Science, University of Missouri, Rolla, MO, USA, <sup>3</sup>Brooks Automation, CA, USA, <sup>4</sup>Dept. of Electrical Engineering, Washington University, St. Louis, USA, <sup>5</sup>Dept. of Electrical Engineering, Michigan State University, MI, USA)

## TH2\_1\_3 Integrated Sensor Design Using Ion Channels Inserted into Lipid Bilayer Membranes,

M. Goryll<sup>1</sup>, S. Wilk<sup>1</sup>, G.M. Laws<sup>1</sup>, S.M. Goodnick<sup>1</sup>, T.J. Thornton<sup>1</sup>, M. Saraniti<sup>2</sup>, J.M. Tang<sup>3</sup>, and R.S. Eisenberg<sup>3</sup>, (\*Arizona State University, Dept. of Electrical Engineering, Tempe, AZ 85287, USA, \*Illinois Institute of Technology, Dept. of Electrical and Computer Engineering, Chicago, IL 60616, USA, \*Rush Medical College, Dept. of Molecular Biophysics and Physiology, Chicago, IL 60612, USA)

### TH\_2\_1\_4 Control and Function for DNA Nanodevices,

F.C. Simmel, W.U. Dittmer, and A. Reuter, (Sektion Physik and Center for Nanoscience, University of Munich, Geschwister-Scholl-Platz 1, 80539 München, Germany)

TH2\_1\_5 Experimental Studies of DNA Electrical Properties Using AFM Based Nano-Manipulator,

G. Li<sup>1</sup>, N. Xi<sup>1</sup>, A. Saeed<sup>1</sup>, H. Chen<sup>1</sup>, J. Zhang<sup>1</sup>, W.J. Li<sup>2</sup>, C.K.M. Fung<sup>2</sup>, R.H.M. Chan<sup>2</sup>, M. Zhang<sup>3</sup> and T.-J. Tarn<sup>4</sup>, (\*Dept. of Electrical and Computer Engineering, Michigan State University, East Lansing, Michigan, USA, \*Dept. of Automation & Computer-Aided Engineering, The Chinese University of Hong Kong, Hong Kong, China, \*Life Sciences Division, Agilent Technologies, 3500 Deer Creek Road, Palo Alto, CA 94304, USA, \*Dept. of Systems Science and Mathematics, Washington University at St. Louis, MO 63130, USA)

# 10.45-12.15 SESSION TH2\_2: "DURINT" PROJECT - NANOCIRCUITS (Chair: J. Fortes)

TH2\_2\_1 Choice of Flat-Band Voltage, V<sub>DD</sub> and Diameter of Ambipolar Schottky-Barrier Carbon Nanotube Transistors in Digital Circuit Design,

A. Raychowdhury, J. Guo, K. Roy, and M. Lundstrom, (Dept. of Electrical and Computer Engineering, Purdue University, USA)

## TH2\_2\_2 Design and Performance Analysis of Novel Nanoscale Associative Memory,

B.A. Davis, J.C. Principe, and J.A.B. Fortes, (Electrical and Computer Engineering, University of Florida, Gainesville, FL, 32611, USA)

### TH2\_2\_3 On Single Electron Technology Full Adders,

M. Sulieman and V. Beiu (School of EE&CS, Washington State University, Pullman, WA, 99163-2752, USA)

## TH2\_2\_4 New Complementary Logic Circuits Using Coupled Quantum Wells,

Y. Katayama, (IBM Research, Tokyo Research Laboratory, 1623-14 Shimotsuruma, Yamato, Kanagawa 242-8502, Japan)

TH2\_2\_5 A Circuit Approach for Implementing Quantum Memory,

H.-W. Wang, I.-M. Tsai, S.-Y. Kuo, (Dept. of Electric Engineering, National Taiwan University, Taipei, Taiwan)

## TH2\_2\_6 Binary Addition Based on Single Electron Tunneling Devices,

C. Lageweg, S. Cotofana, S. Vassiliadis, (Electrical Engineering Dept., Delft University of Technology, Delft, The Netherlands)



## 10.45-12.15 SESSION TH2\_3: NANOELECTRONICS 4 (Chair: R. Ragan)

TH2\_3\_1 Suppression of Quantum Interference Induced Vortices and Threshold Voltage Shift Due to the Inclusion of Inelastic Scattering in Ultra Small Fully Depleted SOI MOSFETs,

M.J. Gilbert and D.K. Ferry, (Dept. of Electrical Engineering and Center for Solid State Electronics Research, Arizona State University, Tempe, AZ 85287-5706, USA)

TH2\_3\_2 Quantum Mechanical and Transport Aspects of Resolving Discrete Charges in Nano-CMOS Device Simulation,

A. Asenov, G. Roy, C. Alexander, A.R. Brown, J.R. Watling and S.

Roy, (Device Modeling Group, Dept. Electronics & Electrical Engineering, University of Glasgow, Glasgow G12 8LT, Scotland)

## TH2\_3\_3 Three-Dimensional Simulation of Single Electron Transistors,

G. Fiori<sup>1</sup>, M. Pala<sup>1</sup>, and G. lannaccone<sup>1,2</sup>, (\*Dipartimento di Ingegneria dell'Informazione, Universit`a degli Studi di Pisa, Via Caruso, I-56122 Pisa, Italy, <sup>2</sup>IEIIT-CNR, Pisa, Italy)

## TH2\_3\_4 How Quantum Effects and Unintentional Doping Affect the Threshold Voltage of Narrow-Width SOI Devices,

D. Vasileska and S.S. Ahmed, (Dept. of Electrical Engineering, Arizona State University, Tempe AZ, 85287-5706, USA)

### TH2\_3\_5 The Computational Abilities of Fixed Random Structures,

J.C. Lusth and E.A. Skaug, (University of Arkansas, Fayetteville, AR, 72701, USA, University of Wisconsin, Madison, WI, 53719 USA)

### TH2\_3\_6 Power Dissipation in Nanomagnetic Logic Devices,

G. Csaba<sup>1</sup>, P. Lugli<sup>1</sup>, W. Porod<sup>2</sup>, (\*Institute for Nanoelectronics, Technical University of Munich, Arcisstrasse 21, D-80333 Munich, Germany, \*Center for Nano Science and Technology, Electrical Engineering Dept., University of Notre Dame, 275 Fitzpatrick Hall, Notre Dame, IN 46556, USA)

12.30-14.15 Award Lunch

### 14.45-15.45 **SESSION TH3\_1** (Late news papers)

## 14.45-15.45 SESSION TH3\_2: NANOMANIPULATION (Chair: F. Arai)

TH3\_2\_1 Nanomanipulation with 3D Visual and Force Feedback using Atomic Force Microscopes,

W. Vogl<sup>1</sup>, M.Sitti<sup>2</sup>, M.F. Zäh<sup>1</sup>, (¹iwb, Technische Universität München, Garching 85748, Germany, ²NanoRobotics Laboratory, Carnegie Mellon University, Pittsburgh, PA 15213, USA)

## TH3\_2\_2 Augmented Reality Enhanced "Top-Down" Nano-Manufacturing,

G. Li, N, Xi, H. Chen, and A. Saeed, (Dept. of Electrical and Computer Engineering, Michigan State University, East Lansing, Michigan, USA)

## TH3\_2\_3 Haptically Generated Paths of an AFM-Based Nanomanipulator Using Potential Fields,

M. Ammi and A. Ferreira, (Laboratoire Vision et Robotique, 10, Boulevard, Lahitolle, 18000, Bourges, France)

## TH3\_2\_4 The Nanostructured Origami<sup>™</sup> 3D Fabrication and Assembly Process for Nanomanufacturing,

H.J. In<sup>1</sup>, W. Arora<sup>2</sup>, T. Buchner<sup>1</sup>, S.M. Jurga<sup>1</sup>, H.I. Smith<sup>2</sup>, G. Barbastathisa<sup>1</sup>, (\*Dept. of Mechanical Engineering, \*2Dept. of Electrical Engineering and Computer Science, Massachusetts Institute of Technology, Cambridge, MA 02139, USA)

# 14.30-18.10 SESSION TH\_SP: SPECIAL SYMPOSIUM ON "Applications of Nanotechnology in Medicine" (Chair: B. Wolf)

### 14.30-14.45 TH\_SP\_1 Opening remarks and introduction

B. Wolf (Heinz Nixdorf Lehrstuhl für Medizinische Elektronik, TU München, Munich, Germany)

## 14.45-15.15 TH\_SP\_2 Nanobiotechnology meets medical technology: propects and demands

D. Wechsler, (Verband Deutsche Ingenieure, Germany)

### 15.15-15.45 TH\_SP\_3 Applications on Nanotechnology in Medicine

C. Alexiou, (Dept. Otorhinolaryngology, head and neck surgery, Friedrich-Alexander-Unveristäa, Erlangen, Germany)

## 15.45-16.05 TH\_SP\_4 New magnetic FeCoPt nanoparticles for biotechnology

A. Hütten, (Thin Films and Nanostructures, Unversität. Bielefeld, Bielefeld, Germany)

## 16.05-16.25 TH\_SP\_5 Field-controlled motion of sub-nano, nano and macroparticles

M. Koch, (Heinz Nixdorf Lehrstuhl für Medizinische Elektronik, TU München, Munich, Germany)

16.25-16-45 TH\_SP\_6 Drug delivery for nerve tissue regeneration

F. C. Soumetz<sup>1</sup>, M. Giacomini<sup>1</sup>, L. Pastorino<sup>1</sup>, J. B. Phillips<sup>2</sup>, R. A. Brown<sup>2</sup>, C. Ruggiero<sup>1</sup>, (D.I.S.T. University of Genova, Via Opera Pia, 13, 16145 Genova, Italy, <sup>2</sup>University College London, Tissue Repair and Engineering Centre, United Kingdom)

#### 16.45-17.15 Coffee break

## 17.15-17.35 TH\_SP\_7 Localized nucleic acid delivery to living cells using nanobiotechnology approaches

C. Plank, (Institute of experimental oncology, Klinikum Rechts der Isar, TU München, Munich, Germany)

17.35-17.55 TH\_SP\_8 Magnetorelaxometry of magnetic nanoparticles: a new method for the quantitative and specific analysis of biomolecules

F. Ludwig, (Institute für Elektrische Messtechnik und Grunlagen der Elektrotechnik, TU Braunschweig, Braunschweig, Germany)

17.55-18.15 TH\_SP\_9 Aerosol delivery of DNA-loaded nanoparticles: factors influencing particle stability and gene transfer efficiency

C. Rudolph, (Haunersches Kinderspital, Klinikum der Ludwig Maximillian Universität München, Munich, Germany)

18.15-18.35 TH\_SP\_10 Atomic Force Microscopy in Ophthalmic Surgery

M.P. De Santo<sup>1</sup>, M. Lombardo<sup>2</sup>, S. Serrao<sup>2</sup>, G. Lombardo<sup>1</sup>, and R. Barberi<sup>1</sup>, (<sup>1</sup>LICRYL – Dept. of Physics, Università della Calabria, Arcavacata di Rende, 87036, <sup>2</sup>Dept. of Ophthalmology, Catholic University of Rome, Rome, Italy)

## 18.35-18.55 TH\_SP\_11 Technical and physical aspects of controlling magnetic nanoparticles

T. Weyh and B. Gleich, (Heinz Nixdorf Lehrstuhl für Medizinische Elektronik, TU München, Munich, Germany)

### POSTER SESSION I (Tuesday, Aug. 17<sup>th</sup>)

### TU-P1 Compact Current and Current Noise Models for Single-Electron Tunneling Transistors,

H. Chaohong<sup>1,2</sup>, S.D. Cotofana<sup>1</sup>, and J. Jianfei<sup>2</sup>, (\*Computer Engineering Laboratory, Delft University of Technology, Delft, The Netherlands, \*Research Institute of Micro/Nano Science and Technology, Shanghai Jiao Tong University, China)

### TU-P2 Quantum Well Electron Dynamics in a Parallel Magnetic Field,

N.J.M. Horing<sup>1</sup>, M.L. Glasser<sup>2</sup>, B. Dong<sup>1</sup> (\*Dept. of Physics and Engineering Physics, Stevens Institute of Technology, Hoboken, New Jersey 07030, USA, \*Dept. of Physics, Clarkson University, Potsdam, New York 13699, USA)

### TU-P3 Plasmon Resonances in Terahertz Photoconductivity,

N.J.M. Horing, (Dept. of Physics and Engineering Physics, Stevens Institute of Technology, Hoboken, New Jersey 07030, USA)

## TU-P4 Change In Electrical Characteristics Of Gallium Phosphide Nanowire Transistors Under Different Environments,

D. Kang<sup>1</sup>, W. Park<sup>1</sup>, B. Kim<sup>2</sup>, J. Kim<sup>2</sup>, C. Lee<sup>3</sup> (\*Materials and Devices Lab, Samsung Advanced Institute Of Technology, Yongin City, Korea 449-712, \*Chonbuk National University, Chonju 561-756, Korea, \*Dept. of Nanotechnology, Hanyang University, Seoul 133-791, Korea)

TU-P5 Correlation Between Plasmon Absorption and Terahertz Photoconductance in a Grid-Gated Double-Quantum Well FET, V.V. Popov<sup>1</sup>, T.V. Teperik<sup>1</sup>, Yu.N. Zayko<sup>1</sup>, S.J. Allen<sup>2</sup>, N.J.M. Horing<sup>3</sup>,

(<sup>1</sup>Institute of Radio Engineering and Electronics (Saratov Division), Russian Academy of Sciences, 410019 Saratov, Russia, <sup>2</sup>Center for Terahertz Science and Technology, University of California, Santa Barbara, California, 93106, USA, <sup>3</sup>Dept. of Physics and Engineering Physics, Stevens Institute of Technology, Hoboken, New Jersey 07030, USA)

## TU-P6 Fabrication of CaF2/Si/CaF2 Resonant-Tunneling Diodes by B-Surfactant Enhanced Epitaxy of Si Quantum-Well Layers,

C.R. Wang, M. Bierkandt, B.H. Müller, E. Bugiel, and K.R. Hofmann, (Institute for Semiconductor Devices and Electronic Materials, University of Hannover, Appelstr. 11A, 30167 Hannover, Germany)

### TU-P7 Microtubules and Neuronal Nanobioelectronics,

S.E. Lyshevski, T. Renz\*, (Dept. of Electrical Engineering, Rochester Institute of Technology Rochester, New York, 14623-5603, USA, \*Air Force Research Laboratory, Information Technology Directorate, 26 Electronic Parkway, Rome NY 13441, USA)

### TU-P8 Carbon-Based Nanoelectronics: NanoICs with Fullerenes,

S.E. Lyshevski, (Dept. of Electrical Engineering, Rochester Institute of Technology, Rochester, New York, 14623-5603, USA)

## TU-P9 Semi-Empirical SPICE Models for Carbon Nanotube FET Logic,

C. Dwyer, M. Cheung, and D.J. Sorin, (Dept. of Electrical and Computer Engineering, Duke University, Durham, NC 27708, USA)

## TU-P10 Electrical and Material Characteristics of the Sub 5 nm Hafnium Doped Tantalum Oxide High k Film,

J. Lu and Y. Kuo, (The Thin Film Nano and Microelectronics Research Laboratory, Texas A&M University, College Station, TX, 77843-3122, USA)

## TU-P11 SPICE Implementation of a Compact Single Electron Tunneling Transistor Model,

C. Jia<sup>1,2</sup>, H. Chaohong<sup>1,2</sup>, S.D. Cotofana<sup>1</sup>, and J. Jianfei<sup>2</sup>, (¹computer Engineering Laboratory, Delft University of Technology, Delft, The Netherlands, ²Research Institute of Micro/Nano Science and Technology, Shanghai Jiao Tong University, China)

## TU-P12 Quantum Simulation of Nano-Scale Schottky Barrier MOSFETs,

M.Shin<sup>1</sup>, M. Jang<sup>2</sup>, S. Lee<sup>2</sup>, (\*School of Engineering, Information and Communications University, Daejeon 305-714, Korea, \*Nano-Electronics Device Team, ETRI, Daejeon 305-330, Korea)

## TU-P13 Regular Array of Nanometer-Scale Devices Performing Logic Operations with Fault-Tolerance Capability,

A. Schmid and Y. Leblebici, (Microelectronic Systems Laboratory, Swiss Federal Institute of Technology, CH-1015 Lausanne, Switzerland)

TU-P14 The Tunneling Field Effect Transistor (TFET) Used in a Single-Event-Upset (SEU) Insensitive 6 Transistor SRAM Cell in Ultra-Low Voltage Applications,

T. Nirschl<sup>1,2</sup>, S. Henzler<sup>1</sup>, C. Pacha<sup>3</sup>, P.-F.Wang<sup>1</sup>, W. Hansch<sup>1</sup>, G. Georgakos<sup>2</sup>, and D. Schmitt-Landsiedel<sup>1</sup>, (<sup>1</sup>Technical University Munich, Institute for Technical Electronics, Theresienstrasse 90, 80290 Munich, Germany, <sup>2</sup>Infineon Technologies, Corporate Logic, <sup>3</sup>Infineon Technologies, Corporate Research)

TU-P15 Resonant Crossover of Terahertz Loss to Gain in a Bloch Oscillating InAs/AISb Super-Superlattice,

P.G. Savvidis<sup>1</sup>, B. Kolasa<sup>1</sup>, and S.J. Allen<sup>1</sup>, G. Lee<sup>2</sup>, (\*Center for Terahertz Science and Technology, University of California, Santa Barbara, California, 93106, USA, \*Agilent Laboratories, 3500 Deer Creek Rd., Palo Alto, CA 94304-1317, USA)

## TU-P16 Optoelectromagnetic Nanocrystals and Microoptoelectromechanical Systems,

M.A. Lyshevski, and S.E. Lyshevski (Microsystems and Nanotechnologies, 70 Angels Path, Webster, NY 14580-4400, USA, Dept. of Electrical Engineering, Rochester Institute of Technology, Rochester, New York 14623-5603, USA,)

TU-P17 Edge Detection at Height Profiles with Nano Resolution, S. Töpfer, R. Mastylo, G. Linß, E. Manske, O. Kühn, U. Nehse, (Technische Universität Ilmenau, Ilmenau, Thuringia, 98693, Germany)

## TU-P18 Visible Frequency of Achromatic Quadrants Wave Plates Using the Artificial Birefringence,

H.-C. Huang<sup>1</sup>, M.-C. Chen<sup>2</sup>, P.-G. Luan<sup>2</sup>, J.-J. Yang<sup>1</sup> and C.-T. Lee<sup>2</sup>, (<sup>1</sup>Mechanical Industry Research Laboratories, Industrial Technology Research Institute, Hsinchu, 310, Taiwan, Republic of China, <sup>2</sup>Institute of Optical Sciences, National Central University, Chung-Li, 32054, Taiwan, Republic of China)

## TU-P19 Light Transmission Through Nanostructured Metal Films: Numerical Modeling and Experiment,

K. Caputa<sup>1</sup>, R. Gordon<sup>1</sup>, and B. Leathem<sup>2</sup>, (\*Dept. of Electrical and Computer Engineering, University of Victoria, Victoria, BC, V8W 3P6, \*Dept. of Physics, Simon Fraser University, Burnaby, BC, V5A 1S6)

TU-P20 Self-Oscillation of Micromechanical Resonators,

C.C. Höhberger, and K. Karrai, (Center for NanoScience, Ludwig-Maximilians-Universität München, Geschwister-Scholl-Platz 1, 80539 München, Germany)

## TU-P21 Annealed InGaAs Quantum Dot Thin p-Clad Laser Diodes for Integration,

P. Lever, M. Buda, H.H. Tan and C. Jagadish, (Dept. of Electronic Materials Engineering, Research School of Physical Sciences and Engineering, Australian National University, Canberra, Australia, 2612)

## TU-P22 Quantum-Wired MOSFET Photodetector Fabricated by Conventional Photolithography on SOI Substrate,

J.-H. Park<sup>1,2</sup>, H. Kim<sup>1</sup>, I.-S. Wang<sup>2</sup>, and J.-K. Shin<sup>2</sup>, (\*Korea Electronics Technology Institute, Kyunggi-do, 451-865, Republic of Korea, \*Dept. of Electronics, Kyungpook National University, Daegu, 702-701, Republic of Korea)

## TU-P23 Dielectrophoretic Integration of Nanodevices with CMOS Circuitry,

S. Evoy<sup>1</sup>, N. DiLello<sup>1</sup>, V. Deshpande<sup>1</sup>, A. Narayanan<sup>2</sup>, and S. Raman<sup>2</sup>, (\*Dept. of Electrical and Systems Engineering, The University of Pennsylvania, Philadelphia, PA 19104, USA, \*Dept. of Electrical and Computer Engineering, Virginia Tech, Blacksburg, VA, 24061, USA.)

TU-P24 Visible Photoluminescence and Conductometric Response of Tin Oxide Nanobelts to NO<sub>2</sub>: Toward a Selective Gas Sensor, G. Faglia<sup>1</sup>, C. Baratto<sup>1</sup>, E. Comini<sup>1</sup>, M. Ferroni<sup>1</sup>, M. Zha<sup>2</sup>, G. Salviati<sup>2</sup>, A. Zappettini<sup>2</sup>, and G. Sberveglieri<sup>1</sup>, (\*INFM and University of Brescia, Sensor Laboratory, Dept. of Chemistry and Physics for Engineering and for Materials, Via Valotti 9, I-25123 Brescia, Italy, \*\*Istituto dei Materiali per l'Elettronica ed il Magnetismo, IMEM Institute - C.N.R., Parco delle Scienze - I-Parma)

## TU-P25 Freely Suspended Nanostructure with No Substrate Beneath: Fabrication and Optical Imaging,

C. Meyer<sup>1</sup>, O. Sqalli<sup>2</sup>, H. Lorenz<sup>1</sup>, and K. Karrai<sup>1</sup>, (\*Center for NanoScience and Physics Dept., Ludwig-Maximilians-University Munich, Germany, \*Attocube Systems, Munich, Germany)

#### TU-P26 A Biomedical Bone Nano Transducer,

K. Singh, (CBME, Indian Institute of Technology, New Delhi-110016, India, and SOET, IGNOU University, New Delhi-110068)

### TU-P27 Preparation of Thermo-Chromic Nanocomposite Films,

G. Carotenuto<sup>1</sup>, B. Martorana<sup>2</sup>, P. Perlo<sup>2</sup>, and L. Nicolais<sup>1</sup>, (\*Inst. of Composite and Biomedical Materials. National Research Council. Napoli – 80125. Italy, \*FIAT Research Center. Orbassano (TO) – 10043. Italy)

## TU-P28 Computational Estimation of Nano-Photocatalyst Activity: Feasibility of Kernel Based Learning Machines,

D.J. Strauss, G. Schäfer, M. Akarsu, and H. Schmidt, (Leibniz-Institute for New Materials, Saarbruecken, Germany)

TU-P29 On Shape Controlled Nanocrystals and Hybrid Materials: How Nanotransistors and Remote Controlled Fluorescent Probes Could Be Realized,

S. Kudera<sup>1</sup>, L. Manna<sup>2</sup>, W.J. Parak<sup>1</sup>, (Lehrstuhl für angewandte Physik, Ludwig-Maximilians Universität München<sup>2</sup> National Nanotechnology Lab of INFM Lecce, Italy)

TU-P30 Catalytic Syntheses of Silicon Nanowires and Silica

#### Nanotubes,

Y.-H. Yang, S.-J. Wu, H.-S. Chiu, P.-I. Lin, and Y.-T. Chen, (Dept. of Chemistry, National Taiwan University, Taipei 106, Taiwan, ROC and Institute of Atomic and Molecular Sciences, Academia Sinica, P.O. Box 23-166, Taipei 106, Taiwan, ROC)

## TU-P31 Improvement in Writing Speed of Electron Beam Direct-Write Lithography,

C.Y. Chen, C.C. Su, J.Y. Huang, J.J. Yang, and H.Y. Lin, (Micro Component Development Dept., Micro Electro-Mechanical Sys. Div., Mechanical Industry Research Laboratories, Industrial Technology Research Institute, Chutung, Hsinchu, 310, Taiwan, ROC)

## TU-P32 Preparation of Nano-Composites by Advanced Colloidal Processing,

H. Sarraf, (Institute of Chemical Technology (I.C.T), Prague, Czech Republic)

## TU-P33 Fabrication of Nanoelectrodes for Hybrid Molecular - Electronic Devices,

A.D. Torre, P. Visconti, G. Maruccio, E. D'Amone, R. Krahne, L. Manna, R. Rinaldi, and R. Cingolani, (National Nanotechnology Laboratory of INFM, University of Lecce, Via per Arnesano, 73100 Lecce, Italy)

## TU-P34 Self Assembly of Nanowires Array with Lattice Directional Growth,

H. Lin, (Dept. of Applied Physics, Cornell University, Ithaca, NY, 14850, USA)

TU-P35 A Hybrid Nanorobotic Manipulation System Integrated with

## Nanorobotic Manipulators Inside Scanning and Transmission Electron Microscopes,

M. Nakajima, F. Arai, L. Dong, and T. Fukuda, (Nagoya University, Nagoya City, 464-8603, Japan)

### TU-P36 Automated Nano-Assembly of Nanoscale Structures,

H. Chen, N. Xi, G. Li, J. Zhang, A. Saeed, (Electrical and Computer Engineering Dept., Michigan State University, East Lansing, MI 48823, USA)

## TU-P37 Atomic Force Microscope Based Nanomanipulator for Mechanical and Optical Lithography,

F.J. Rubio-Sierra, S. Burghardt, A. Kempe, W.M. Heckl, and R.W. Stark, (Center for Nanoscience and Ludwig-Maximilians-Universität München, 80333 Munich, Germany)

## TU-P38 Magnetic Anisotropy in Magnetostatically Coupled Ni<sub>80</sub>Fe<sub>20</sub> Nanowires,

S. Goolaup, N. Singh, A.O. Adeyeye V. Ng, and M.B.A Jalil, (Information Storage Materials Laboratory, Dept. of Electrical and Computer Engineering, National University of Singapore, 4 Engineering Drive 3, Singapore-117576)

## TU-P39 Three-Dimensional Calculation of Electronic Structures in Semiconductor Quantum Ring Based Artificial Molecules,

Y. Li, (Dept. of Computational Nanoelectronics, National Nano Device Laboratories & Microelectronics and Information Systems Research Center, National Chiao Tung University, P.O. BOX 25-178, Hsinchu City, Hsinchu 300, Taiwan)

TU-P40 Control of Drug-Carrying Magnetobeads by Magnetic

#### Gradient-Fields,

T. Weyh, N. Seidl, B. Gleich, C. Alexiou, M. Koch, B. Wolf, (Heinz-Nixdorf-Chair For Medical Electronics, Dept. of Electrical Engineering and Information, Technology, Technische Universität München, Munich, Theresienstr. 90, 80333, Germany)

### TU-P41 Dynamic Marker,

M. Koch, T. Weyh, and B. Wolf, (Technische Universität München, Arcisstrasse 21, D-80290 München, Germany)

### TU-P42 20nm Silicon Nanorods Fabricated by Reactive Ion Etch,

E.-Z. Liang, C.-J. Huang, and C.-F. Lin\*, (Graduate Institute of Electro-optical Engineering, National Taiwan University, ,\* Also with Dept. of Electrical Engineering and Graduate Institute of Electronics Engineering, Taipei, Taiwan, Republic of China)

TU-P43 Inversion Asymmetry Effects in L-Valley Quantum Wells, J.-M. Jancu<sup>1</sup>, R. Scholz<sup>2</sup>, G. C. La Rocca<sup>1</sup>, E. A. de Andrada e Silva<sup>3</sup>, and P. *Voisin*<sup>4</sup>, (\*Scuola Normale Superiore and INFM, Piazza dei Cavalieri 7, I-56126 Pisa, Italy, \*Institut für Physik, Technische Universität, D-09107 Chemnitz, Germany, \*Instituto Nacional de Pesquisas Espaciais, C.P. 515, 12201-970 São José dos Campos - SP, Brasil, \*Laboratoire de Photonique et de Nanostructure, CNRS, route de Nozay, F91000, Marcoussis, France)

## TU-P44 Quantized Conductance in an In-Plane Gated In0.53Ga0.47As Quantum Point Contact,

A. Beyer and D.K. Ferry, (Center for Solid State Electronics Research and Dept. of Electrical Engineering, Arizona State University, Tempe, Arizona, 85287-6206, U.S.A.)

TU-P45 Scattering of Chiral Currents by Quantum Point Contacts,

A. Cresti<sup>1</sup>, G. Grosso<sup>1</sup> and G.P. Parravicini<sup>2</sup>, (\*NEST-INFM and Dipartimento di Fisica "E. Fermi", Università di Pisa, Via Buonarroti 2, I-56127 Pisa, Italy, <sup>2</sup>NEST-INFM and Dipartimento di Fisica "A. Volta", Università di Pavia, Via Bassi 6, I-27100 Pavia, Italy)

TU-P46 Electrical Contacts of Metals to Carbon-Nanotubes for Applications, to Electrical Coupling Between Miniaturized Moving Parts and Sensors,

Y. Tzeng, Y. Chen, C. Liu, and V. Krishnardula, (Dept. of Electrical and Computer Engineering, Auburn University, Auburn, Alabama 36849, USA)

TU-P47 Lattice of Surface-Magic-Clusters: An Ordered Array of Identical Nanostructures,

H.H. Chang<sup>1,2</sup>, M.Y. Lai<sup>1</sup>, J.H. Wei<sup>2</sup>, C.M. Wei<sup>3</sup>, and Y.L. Wang<sup>1,2</sup>, (\*Institute of Atomic and Molecular Sciences, Academia Sinica, Taipei 106, Taiwan, \*Dept. of Physics, National Taiwan University, Taipei 106, Taiwan, \*Institute of Physics, Academia Sinica, Taipei 115, Taiwan)

#### POSTER SESSION II (Wednesday, Aug. 18<sup>th</sup>)

# WE-P1 Temperature Dependence of Electron Transport Through Long Organic Molecules,

A.Yu. Smirnov<sup>1</sup>, L.G. Mourokh<sup>2</sup>, and N.J.M. Horing<sup>2</sup>, (\*D-Wave System, Inc., 320-1985 W. Broadway, Vancouver, British Columbia, Canada V6J 4Y3, \*Dept. of Physics and Engineering Physics, Stevens Institute of Technology, Hoboken, New Jersey 07030, USA)

## WE-P2 Resonant Electron Tunneling Through Azurin in Air and Liquid by Scanning Tunneling Microscopy,

V. Frascerra, F. Calabi, G. Maruccio, P.P. Pompa, R. Cingolani, R. Rinaldi, (National Nanotechnology Laboratory of INFM, University of Lecce, Via per Arnesano, 73100 Lecce, Italy)

# WE-P3 A Two-Level Redundancy Scheme for Enhancing Scalability of Molecular-Based Crossbar Memories,

Y.-H. Choi<sup>1</sup>, M.-H. Lee<sup>1</sup>, and Y. K. Kim<sup>2</sup>, (\*Dept. of Computer Engineering, \*Dept. of Chemical Engineering, Hongik University, Seoul, Korea)

# WE-P4 STM Assisted *In-Situ* Spectroscopy on Nano-Sized Crystallites of Organic Semiconductors,

K. Hänel, L. Ruppel, G. Witte, A. Birkner, and C. Wöll, (Physikalische Chemie I, Ruhr-Universität Bochum, 44780 Bochum, Germany)

#### WE-P5 Electron-Phonon Scattering in Molecular Wires,

A. Pecchia<sup>1</sup>, A. Gagliardi<sup>2</sup>, A. Di Carlo<sup>1</sup>, T. Frauenheim<sup>2</sup>, P. Lugli<sup>1,3</sup>, (<sup>1</sup>Dipartimento di Ingegneria Elettronica, Universitá di Roma "Tor Vergata", 00133 Roma, Italy, <sup>2</sup>Dept. of theoretical physics, University of Paderborn, D-33098 Paderborn, Germany, <sup>3</sup>Institute of nanoelectronics, University of Munich, TU-Munich, Germany)

## WE-P6 Device for Conductance Measurements of Molecular Systems,

M. Lambacher<sup>1</sup>, C.J.-F. Dupraz<sup>1</sup>, U. Beierlein<sup>1</sup>, J.P. Kotthaus<sup>1</sup>, U.S. Schubert<sup>2</sup>, P.R. Andres<sup>2</sup>, (\*Center for NanoScience and Sektion Physik, Ludwig-Maximilians-Universität-München, Geschwister-Scholl-Platz 1, 80539 München, Germany, \*Laboratory of Macromolecular Chemistry and Nanoscience, Eindhoven University of Technology and Dutch Polymer Institute, P. O. Box 513, 5600 MB Eindhoven, The Netherlands)

### WE-P7 Practical Aspects of Electron Transport Through Single Molecules,

J.M. Seminario, (Dept. of Electrical Engineering, University of South Carolina, Columbia, South Carolina 29208, USA)

WE-P8 Effects of Synthesis Conditions on the Growth of MWCNTs Using an Ultra Sonic Evaporator with Pyrolysis of Hydrocarbon, N.J. Jeong, K.S. Song, S.J. Lee, I.S. Ryu, S.P. Yu and Y.S. Seo, (Korea Institute of Energy Research, 71-2, Jang-Dong, Yuseong-gu, Daejeon, 305-343, Korea)

WE-P9 Functionalization and Dispersion in a Polymer-Matrix of Single-Wall Carbon Nanotubes: a FT-IR Study,

A. Curulli<sup>1</sup>, F. Valentini<sup>2</sup>, S. Orlanducci<sup>2</sup>, E. Tamburri<sup>2</sup>, M. L. Terranova<sup>2</sup>, S. Nunziante Cesaro<sup>1</sup>, and G. Palleschi<sup>2</sup>, (\*ISMN CNR Division 2, Rome, Italy, via del Castro Laurenziano 7, 00161 Rome, Italy, \*Dept. of Chemistry, Tor Vergata University, via della Ricerca Scientifica 1, 00133 Rome, Italy)

### WE-P10 Carbon Nanotubes Analysis, Classification and Characterization,

M.A. Lyshevski, (Microsystems and Nanotechnologies, Webster, NY, 14580, USA)

WE-P11 Carbon Nanotube/Conducting Polymer Composites for Electronic Application: Materials Preparation and Devices Assembling,

F. Brunetti<sup>1</sup>, E. Tamburri<sup>2</sup>, A. Reale<sup>1</sup>, A. Di Carlo<sup>1</sup>, P. Lugli<sup>3</sup>, S. Orlanducci<sup>2</sup>, M.L. Terranova<sup>2</sup>, A. Fiori<sup>2</sup>, (\*Dept. of Electronic Engineering, Univ. Rome Tor Vergata, Rome, 00133 Italy, \*Dept. of Science and Chemical Technology, Univ. of Rome Tor Vergata, Rome, 00133 Italy and INFM, \*Lehrstuhl für Nanoelektronik, TU München Arcisstrasse 21 D-80333 München, Germany)

# WE-P12 Controlled Growth of Ordered SWCNTs for the Realization of Multielectrode Field Emitter Devices,

F. Brunetti<sup>1</sup>, P. Regoliosi<sup>1</sup>, A. Reale<sup>1</sup>, A. Di Carlo<sup>1</sup>, M.L.Terranova<sup>2</sup>, S. Orlanducci<sup>2</sup>, A. Fiori<sup>2</sup>, E. Tamburri<sup>2</sup>, V. Sessa<sup>2</sup>, A. Ciorba<sup>3</sup>, M. Rossi<sup>3</sup>, M. Cirillo<sup>4</sup>, V. Merlo<sup>4</sup>, (\*Dept. of Electronic Engineering, Univ. Rome Tor Vergata, Rome, 00133 Italy, \*Dept. of Science and Chemical Technology, Univ. of Rome Tor Vergata, Rome, 00133 Italy and INFM, \*3Dept. of Energetics, Univ. of Rome La Sapienza, Rome, 00100 Italy, \*Dept. of Physics, Univ. of Rome Tor Vergata, Rome, 00133 Italy and INFM)

### WE-P13 Atomistic Study of the Role of Contact Properties on Nanotube Conduction,

D. Kienle and A. Ghosh (School of Electrical and Computer Engineering, Purdue, University, W. Lafayette, IN 47907, USA)

### WE-P14 Controlled Growth of Carbon Nanotubes on Microstructured Surfaces,

Y.Keles<sup>1,2</sup>, M. Milas<sup>2</sup>, V. Thommen<sup>3</sup>, S. Fahlbusch<sup>4</sup>, T. Stöckli<sup>1</sup>, E. Meyer<sup>3</sup>, L. Forró<sup>2</sup>, H.F. Knapp<sup>1</sup>, (¹CSEM Centre Suisse d'Electronique et de Microtechnique SA, Alpnach Dorf, CH-6055, Switzerland, ²Institute of Physics of Complex Matter, FSB-EPFL, Lausanne, CH-1015, Switzerland, ³Institut für Physik der Universität Basel, Basel, CH-4056, Switzerland, ⁴Materials Technology Dept., EMPA, Thun, CH-3602, Switzerland)

## WE-P15 Individual Single-Walled Carbon Nanotubes with Vertical Alignment,

T. Kato<sup>1</sup>, G.-H. Jeong<sup>1</sup>, T. Hirata<sup>1</sup>, R. Hatakeyama<sup>1</sup>, and K. Tohji<sup>2</sup>, (<sup>1</sup>Graduate School of Engineering, Tohoku University, Sendai 980-8579, Japan, <sup>2</sup>Graduate School of Environmental Studies, Tohoku University, Sendai 980-8579, Japan)

WE-P16 Electric Transport Properties of Single-Walled Carbon Nanotubes Functionalized by Plasma Ion Irradiation Method, G.-H. Jeong<sup>1</sup>, T. Izumida<sup>1</sup>, T. Hirata<sup>1</sup>, R. Hatakeyama<sup>1</sup>, Y. Neo<sup>2</sup>, H. Mimura<sup>2</sup>, K. Omote<sup>3</sup>, Y. Kasama<sup>3</sup>, S.-H. Jhang<sup>4</sup>, and Y.-W. Park<sup>4</sup>, (\*Dept. of Electronic Engineering, Tohoku University, Sendai 980-8579, Japan, \*Research Institute of Electronics, Shizuoka University, Hamamatsu 432-8011, Japan, \*Ideal Star Corporation, Minami-Yoshinari 6-6-3, Aoba-ku, Sendai 989-3204, Japan, \*School of Physics, Seoul National University, Seoul 151-747, Korea)

WE-P17 Multi-Physics Analysis for Assembling of Nano Particle Under the Mixture Condition of the Dielectric Fluid and AC Electric Field.

S.-K. Kwon<sup>1</sup>, S.-H. Kim<sup>1</sup>, Y.-E. Yoo<sup>2</sup>, E.-S. Lee<sup>2</sup>, C.-S. Han<sup>2</sup>, (\*KAIST, 373-1 Guseong, Yousung, Daejeon, 305-7-1, Rep. of Korea, \*KIMM, 171 Jang, Yousung, Daejeon, 305-343, Rep. of Korea)

WE-P18 Assembly of Carbon Nanotubes onto Arrays of Microfabricated Test Patterns for the Design of Nanoelectronic Devices.

M. Dipasquale<sup>1</sup>, F. Gatti<sup>2</sup>, D. Ricci<sup>1</sup>, D. Caviglia<sup>1</sup> and E. Di Zitti<sup>1</sup>, (\*Dept. of Biophysical and Electronic Engineering, \*Dept. of Physics, University of Genoa, Genoa, 16145, Italy)

#### WE-P19 Ultrathin Capsules: Novel Artificial Cellular Carriers,

A.J. Khopade\*, F. Caruso, and H. Möhwald, (Max Planck Institute of Colloids and Interfaces, D-14424 / Potsdam, Golm Germany, \* Sun Pharma Advanced Research Centre, Tandalja, Baroda – 390 020 GJ, India)

WE-P20 Robust Entropy-Enhanced Frequency-Domain Genomic Analysis Under Uncertainties,

S.E. Lyshevski and F.A. Krueger, (Dept. of Electrical Engineering, Rochester Institute of Technology, Rochester, NY 14623-5603, USA)

WE-P21 Quantum Theory and High-Fidelity Mathematical Models of DNA,

M.A. Lyshevski, (Microsystems and Nanotechnologies, 70 Angels Path, Webster, NY 14580-4400, USA)

WE-P22 Atomic Force Microscopy in Ophthalmic Surgery, M.P. De Santo<sup>1</sup>, M. Lombardo<sup>2</sup>, S. Serrao<sup>2</sup>, G. Lombardo<sup>1</sup>, and R. Barberi<sup>1</sup>, (\*LICRYL – Dept. of Physics, Università della Calabria, Arcavacata di Rende, 87036, \*Dept. of Ophthalmology, Catholic University of Rome, Rome, Italy)

# WE-P23 Probing Lipid Membranes and Ion Channels with High Frequency Spectroscopy,

M. Olapinski<sup>1</sup>, A. Brüggemann<sup>2</sup>, M. George<sup>2</sup>, S. Manus<sup>1</sup>, N. Fertig<sup>2</sup>, and F.C. Simmel<sup>1</sup>, (\*Sektion Physik and Center for Nanoscience, University of Munich, Geschwister-Scholl-Platz 1, 80539 München, Germany, \*2Nanion Technologies GmbH, Pettenkoferstr. 12, 80336 München, Germany)

## WE-P24 DNA-Mediated Assembly of Gold Nanoparticles Influenced by Cations,

U. Rehn<sup>1</sup>, R.B. Wehrspohn<sup>2</sup> and U. Gösele<sup>1</sup>, (<sup>1</sup> Max Planck Institute of Microstructure Physics, 06120 Halle, Germany, <sup>2</sup>University of Paderborn, Dept. of Physics, 33098 Paderborn, Germany)

WE-P25 Drug delivery for nerve tissue regeneration, F. C. Soumetz<sup>1</sup>, M. Giacomini<sup>1</sup>, L. Pastorino<sup>1</sup>, J. B. Phillips<sup>2</sup>, R. A. Brown<sup>2</sup>, C. Ruggiero<sup>1</sup>, (\*D.I.S.T, University of Genova, Via Opera Pia, 13, 16145 Genova, Italy, <sup>2</sup>University College London, Tissue Repair and Engineering Centre, United Kingdom)

WE-P26 Yeast Cytochrome C on Gold Electrode: A Robust Hybrid

#### System for Bio-Nanodevices,

B. Bonanni, D. Alliata, L.Andolfi, A.R. Bizzarri, I. Delfino, S.

Cannistraro, (Biophysics and Nanoscience Centre, INFM, Dipartimento di Scienze Ambientali, Università della Tuscia, Largo dell'Università, I-01100, Viterbo, Italy)

#### WE-P27 Nanotechnology and Medicine,

S. Thalhammer and W.M. Heckl, (Dept. for Geo- and Environmental Sciences, University of Munich, Theresienstr. 41, 80333 Munich, Germany)

### WE-P28 Experimental Study of Tunnelling Through Nanogap Electrodes in Neural Network,

A.K. Ray<sup>1</sup>, A. Bandyopadhyay<sup>1</sup> and S.I. Khondaker<sup>2</sup>, (\*Nanotechnology Research Laboratories, School of Engineering, Sheffield Hallam University, City Campus, Pond Street, Sheffield S1, 1WB, UK, \*Center for Nano- & Molecular Science and Technology, The University of Texas at Austin, 1 University Station, A5300, Austin, TX 78712, USA)

#### WE-P29 Quantum Systems Versus Classical Networks,

P.P. Civalleri and M. Gilli, (Politecnico di Torino, Corso Duca degli Abruzzi, 24, I–10129 Torino,)

# WE-P30 A Fault-Tolerant Architecture for Nanoelectronic Signal Processing,

H. Fujisaka, D.Hamano, T. Kamio, and M. Sakamoto, (Faculty of Information Sciences, Hiroshima City University, 3–4–1 Ozuka-higashi, Asa-minami-ku, Hiroshima, 731-3194 Japan)

WE-P31 Multiplexing Schemes for Cost-Effective Fault-Tolerance,

S. Roy and V. Beiu, (School of EE&CS, Washington State University, Pullman, WA 99164-2752, USA)

### WE-P32 Useful Logic Blocks Based on Clocked Series-Connected RTDs,

H. Pettenghi, Maria J. Avedillo and J.M. Quintana, (Instituto de Microelectrónica de Sevilla, Centro Nacional de Microelectrónica, Edificio CICA, Avda. Reina Mercedes s/n, 41012-Sevilla, Spain)

### WE-P33 Quantum Boolean Circuits Construction Using Tabulation Method.

C.-Y. Lu, S.-A.Wang, and S.-Y. Kuo, (Dept. of Electrical Engineering and Graduate Institute of Electronic Engineering, National Taiwan University, Taipei, Taiwan)

## WE-P34 Reliability Evaluation of von Neumann Multiplexing Based Defect-Tolerant Majority Circuits.

D. Bhaduri and S.K. Shukla, (Fermat Lab, Bradley Dept. of Electrical and Computer Engineering, Virginia Polytechnic Institute and State University, Blacksburg, VA 24061, USA)

## WE-P35 Reliability Analysis for Defect-Tolerant Nano-Architectures in the Presence of Interconnect Noise,

D. Bhaduri and S.K. Shukla, (Fermat Lab Bradley Dept. of Electrical and Computer Engineering, Virginia Polytechnic Institute and State University, Blacksburg, VA 24061, USA)

WE-P36 Effective Electrostatic Discharge Protection Circuit Design Using Novel Full-Silicided N-MOSFETs in Sub-100 nm Era, J.W. Lee<sup>1</sup>, Y. Li<sup>1.2</sup>, and H. Tang<sup>3</sup>, (\*Dept. of Computational Nanoelectronics, National

Nano Device Laboratories, <sup>2</sup>Microelectronics and Information Systems Research Center, National Chiao Tung University, <sup>3</sup>United Microelectronics Corporation, Science Industrial Park, Hsinchu 300, Taiwan)

## WE-P37 Modeling and Analysis of Carbon Nanotube Interconnects and Their Effectiveness in High Speed VLSI Design,

A. Raychowdhury, and K. Roy, (Dept. of Electrical and Computer Engineering, Purdue University, USA)

### WE-P38 An Efficient Functional Verification Method for Quantum Boolean Circuits,

S.-A. Wang, C.-Y. Lu, and S.-Y. Kuo, (Dept. of Electrical Engineering and Graduate Institute of Electronic Engineering, National Taiwan University, Taipei, Taiwan)

#### WE-P39 Design of Multi-Valued QMOS Pre-Decoder,

H. Zhang<sup>1</sup>, T. Uemura<sup>1</sup>, P. Mazumder<sup>1</sup>, and K. Yang<sup>2</sup>, (\*) The University of Michigan, Ann Arbor, MI, 48105, USA, <sup>2</sup>KAIST, Republic of Korea)

## WE-P40 Design and Analysis of SET Circuits: Using MATLAB Modules and SIMON,

M. Sulieman and V. Beiu, (School of Electrical Engineering and Computer Science, Washington State University, Pullman, WA 99164-2752, USA)

## WE-P41 Using Quantum Model of Computation for Reliability Evaluation of Defect Tolerant Nano-Architectures,

D. Bhaduri and S.K. Shukla, (Fermat Lab, Bradley Dept. of Electrical and Computer Engineering, Virginia Polytechnic Institute and State University, Blacksburg, VA 24061, USA)

### WE-P42 Complex Majority Gate Implementations of Quantum Dot Cellular Automata,

W.J. Townsend and J.A. Abraham, (Computer Engineering Research Center, The University of Texas at Austin, Austin, TX 78712, USA)

#### WE-P43 On Nanoelectronic Architectural Challenges and Solutions,

V. Beiu<sup>1</sup>, U. Rückert<sup>2</sup>, S. Roy<sup>1</sup>, and J. Nyathi<sup>1</sup>, (Centres for Neural-Inspired Nano Architectures, <sup>1</sup>School of EE&CS, Washington State University, Pullman, WA 99164-2752, USA, <sup>2</sup>Heinz-Nixdorf Institute, University of Paderborn, 33102 Paderborn, Germany)

# WE-P44 Performance of Organic Photodetectors with Bulk Heterojunctions,

T. Rauch, D. Henseler, P. Schilinsky, C. Waldauf, J. Hauch, C.J. Brabec (Siemens AG, Erlangen, Germany)

#### WE-P45 Nanomagnetism and Domain Structure of Sintered Nickel-Zinc Ferrites Studied by Magnetic Force Microscopy,

A. Dias (Departamento de Engenharia Metalúrgica e de Materiais Universidade Federal de Minas Gerais, Belo Horizonte-MG, Brazil)

# A

Abraham J.A. **WE-P42** Abstreiter G. WE2 2 6 Acred B. TH1\_3\_4 Adeyeye A.O. TU2\_2\_4, TU-P38 Ahmed S.S. TH2\_3\_4 Akarsu M. **TU-P28** Akis R. WE1\_1\_3 Albrecht P.M. TU1\_1\_4 Albrecht T. WE1\_1\_5 Alexander C. TH2\_3\_2

Alexiou C. TH\_SP\_3, TU-P40 Allen S.J. TU-P15, TU-P5 Alliata D. **WE-P26** Ammi M. TH3\_2\_3 Amro N. TU2\_2\_2 An S.J. TU2\_3\_4 Anantram M. P. WE1\_1\_1 Anderson S. TH1\_3\_4 Andolfi L. **WE-P26** Andres P.R. WE-P6 Anni M. WE3\_1\_3 Arai F.

TU1_3_4, TU-P35 , WE1_3_2, WE1_3_4, WE2_3_2	Bakajin O. <b>TU3_2_3</b> Bakueva L.
Arakawa Y.  WE3_1_1  Arisi E.  WE1_2_2	TU1_2_1 Ballard J. TU2_2_5 Bandyopadhyay A.
Arora W.  TH3_2_4  Asenov A.	WE-P28, TU3_1_5  Baratto C.  TU-P24
TH2_3_2 Avedillo M. J. WE-P32 Avouris P.	Barbastathisa G.  TH3_2_4  Barberi R.  WE-P22
TU1_1_1  B	Basagalar A.  WE2_1_4  Bauer J.  WE2_2_6  Bauer T.M.
Bai P.  TU3_2_5  Baik S.J.  TU2_1_2	TU1_2_5  Bayot V.  TH1_3_2  Beck M.  WE2_3_3

Bednarz L.	Biasco A.
TH1_3_2	TU3_2_4
Beierlein U.	Bierkandt M.
WE-P6	TU-P6
Beiu V.	Birkner A.
TH2_2_3, WE-P31,	WE-P4
WE-P40, WE-P43	Bizzarri A.R.
Belcher Angela	WE-P26
WE_PL_2	Blick R.H.
Beltram F.	TH1_1_1
TU3_1_2	Bogaart E.W.
Bergenti I.	TU2_3_5
WE1_2_2	Bollaert S.
Bernstein G. H.	TH1_3_2, TU3_1_4
WE1_2_1, WE2_3_4	Bonanni B.
Bertoni A.	WE-P26
TU3_2_1	Borgström M.
Beyer A.	<b>WE2_3_3</b>
TU-P44	Boutry H.
Bhaduri D.	ŤH1_3_2
WE-P34, WE-P35,	Boyd E.
WE-P41	TU3_1_3
Bhattacharya S.	Brabec C.J.
TU2 2 6	WF-P44

Bramanti A.  TU3_2_4 Brenner R.  WE3_2_1 Brolo A.G.  TU2_3_2 Brown A.R.  TH2_3_2	Bunk R. WE2_3_3 Bunk W. TU1_3_3 Burghardt S. TU-P37
Brown R.A.	
TH_SP_6 Brüggemann A.	
WE-P23	Cacelli I.
Brunetti F.	WE1_1_4
WE-P11, WE-P12	Cahay M.
Buchner T.	TU3_1_5
TH3_2_4	Calabi F.
Buda M.	WE-P2
TU-P21	Callegari C.
Budiman R.A.	TH1_1_5
WE3_2_3	Cannistraro S.
Buehler T.M.	WE-P26
WE3_2_1	Cao X.
Bugiel E.	TU3_1_3
TU-P6	Cappy A.

```
TH1_3_2, TU3_1_4
                             TH2_1_5
                         Chan V.
Caputa K.
   TU-P19
                             WE3_2_1
Carlberg P.
                         Chang H.H.
   WE2_3_3
                             TU-P47
Carmichael E.
                         Chao T.Y.
                             WE2_3_1
   TU2_2_5
                         Chaohong H.
Carotenuto G.
                             TU-P1, TU-P11
   TU-P27
Carr S.M.
                         Chau R.
   TH1_1_4
                             TU_PL_2
Caruso F.
                         Chen C.Y.
  WE-P19
                           TU-P31
                         Chen H.
Caviglia D.
   WE-P18
                             TH2_1_5, TH3_2_2,
                            TU-P36
Cha H.-S.
 TU1_2_4
                         Chen J.
Chae H.
                             TH1_3_5
   TU2_1_5
                         Chen M.-C.
Chae S.D.
                             TU-P18
   TU2_1_5
                         Chen Y.
Chan P.C.H.
                             TU-P46, TU-P30
   TU3_2_2
                         Cheng G.
Chan R.H.M.
                             TH1_3_6
```

Cheng YT.	Chung M.J.
WE2_3_1	TU1_3_1
Cheung M.	Chung U.I.
TU-P9	TU2_1_2
Chiu HS.	Cingolani R.
TU-P30	TU3_2_4, TU-P33,
Choi J.	WE3_1_3, WE-P2
WE1_1_2	Ciontu F.
Choi M.	TH1_1_3
TU2_1_4	Ciorba A.
Choi S.	WE-P12
TU2_1_2, TU2_1_5	Cirillo M.
Choi YH.	WE-P12
WE-P3	Civalleri P.P.
Chou HM.	WE-P29
TH1_3_1	Clark R.G.
Chou S.	WE3_2_1
WE2_3_5	Colli A.
Chou YC.	WE2_2_2
TU2_1_3	Collier P.A.
Chua L.O.	TU3_2_5
WE2_1_3	Comini E.
Chua T.C.	TU-P24
TU1_2_5	Cotofana S.

TH2_2_6, TU-P1,	TU3_2_4, TU-P33
TU-P11	Datta S.
Courtois B.	TH1_2_3, TU3_1_1
TH1_1_3	Davis B.A.
Craddock I.J.	TH2_2_2
WE3_1_2	de Andrada e Silva E. A.
Cresti A.	TU-P43
TU-P45	De Santo M.P.
Cryan M.J.	WE-P22
WE3_1_2	De Vittorio M.
Csaba G.	WE3_1_3
TH2_3_6, WE1_2_1	Dediu V.
Csurgay Arpad	WE1_2_2
WE2_1_1	Delfino I.
Curatola G.	WE-P26
TU3_1_2	Demers L.
Curulli A.	TU2_2_2
WE-P8	Dermitzaki D.
	WE2_2_5
	Deshpande V.
<b>D</b>	TU-P23
1)	Di Carlo A.
	TU1_1_3, WE1_3_3
D.A. E	WE-P11, WE-P12,
D'Amone E.	

WE-P5	WE1_3_4
Di Gaspare L.	Ducati C.
TU3_1_2	WE2_2_2
Di Zitti E.	Duenas T.
WE-P18	TU2_2_2
Dias A.	Duesberg G.S.
WE-P45	TU1_1_2
Dietl Tomasz	Dupraz C.JF.
WE1_2_3	WE-P6
DiLello N.	Dwyer C.
TU-P23	TU-P9
DilnaS.	Dysart T.J.
TU2_3_5	WE2_1_5
Dipasquale M.	Dzurak A.S.
WE-P18	WE3_2_1
Disawal S.	
TU2_2_2	
Dittmer W.U.	
WE3_3_2	E
Dong B.	
TU-P2	Faglosham D
Dong L.	Eaglesham D.
TU-P35, WE1_3_2,	TU3_2_3
WE2_3_2, TU1_3_4,	Eisenberg R.S.

Ekinci K.L.	WE3_2_2
TH1_1_5	Feng P.
Elgaid K.	TH1_1_5
TU3_1_3	Ferrari A. C.
Elghanian R.	WE2_2_2
TU2_2_2	Ferreira A.
Evangelisti F.	TH3_2_3
TU3_1_2	Ferretti A.
Evoy S.	WE1_1_4
TH1_1_2, TU-P23	Ferroni M.
	TU-P24
	Ferry D.K.
_	TH2_3_1, TU-P44,
F	WE1_1_3
<u>-</u>	Fertig N.
	WE-P23
Fabel S.	Figueiredo R.J.O.
WE3_2_2	WE2_1_4
Faglia G.	<del>-</del> -
TU-P24	Finley J.J.
Fahlbusch S.	WE2_2_6
WE-P14	Fiori A.
Fang Y.P.	WE-P11, WE-P12
TU2_1_3	Fiori G.
	TH2_3_3
Felgenhauer F.	

Forró L.	
WE-P14	
Fortes J.A.B.	
TH2_2_2	G
Fragala J.	
TU2_2_2	Carellanell A
Franciosi A.	Gagliardi A.
WE2_2_2	WE-P5
Frascerra V.	Galloo J.S.
WE-P2	TU3_1_4, TH1_3_2
Frauenheim T.	Gatti F.
WE-P5	WE-P18
Friedman G.	Gaub H.E.
TU2_2_1	WE3_3_3
Frost S.E.	Gayathri S.
WE2_1_5	TU2_3_1
Fujisaka H.	Gelmont B.
WE-P30	WE3_2_4
Fukuda T.	Georgakos G.
	TU-P14
TU-P35, WE1_3_2,	George M.
WE2_3_2, TU1_3_4,	WE-P23
WE1_3_4	Ghosh A.
Fung C.K.M.	WE-P13, TH1_2_3
TH2_1_5, WE1_3_6	Giacomini M.

TH\_SP\_6 TU2 3 2, TU-P19 Goryll M. Gigli G. WE3\_1\_3 TH2\_1\_3 Gösele U. Gilbert M.J. TH2\_3\_1 **WE-P24** Gilli M. Govindan T. R. **WE-P29** WE1\_1\_1 Giovine E. Graham A.P. TU3\_1\_2 TU1\_1\_2 Girlanda M. Grazcyk M. WE1\_1\_4 WE2\_3\_3 Glasser M.L. Greentree A.D. TU-P2 WE3\_2\_1 Gleich B. Griessl S.J.H. TH\_SP\_11, TU-P40 WE2\_2\_1 Gong Q. Grosso G. **TU-P45** TU2\_3\_5 Gonzales T. Gruebele M. TU3\_1\_4 TU2\_2\_5 Guckenberger R. Goodnick S.M. TH2\_1\_3 WE1\_3\_5 Goolaup S. Guckian A. TU2\_2\_4, TU-P38 WE1\_1\_5 Guo J. Gordon R.

TH2_2_1	Hatakeyama R. <b>WE-P15</b> , <b>WE-P16</b>
H	Hauch J.  WE-P44  Hausotte T.
Hackens B. TH1_3_2 Hamano D. WE-P30 Hamilton A.R. WE3_2_1 Han CS. WE-P17 Han J.H. TU2_1_5 Hänel K. WE-P4 Hang Q. WE2_3_4	Haverkort J.E.M.  TU2_3_5 Heck W.M.  WE-P27, TU1_3_3 TU-P37, WE2_2_1 Heidari B.  WE2_3_3 Henseler D.  WE-P44 Henzler S.  TU-P14 Hess Henry  TH2_1_1 Hirata T.
Hansch W.  TU-P14  Harber K.  TH1_3_4	WE-P15, WE-P16 Ho YL.D. WE3_1_2 Hofbauer F.

WE2_2_6	Hu W.
Hofmann K.R.	WE2_3_4
TU-P6	Huang BF.
Hofmann N.	TU1_2_4
WE2_2_4	Huang CJ.
Hofmann S.	TU-P42
WE2_2_2	Huang HC.
Höhberger C.C.	TU-P18
TU-P20	Huang J.Y.
Holland M.	TU-P31
TU3_1_3	Huang X.M.F
Holst M.	TH1_1_5
TU1_2_3	Huo X.
Holt J.K.	TU3_2_2
TU3_2_3	Huo Z.
Horing N.J.M.	TU2_1_2
TU-P2, TU-P3, TU-P5,	Huser T.
WE-P1	TU3_2_3
Hradsky B.	Hütten A.
TH1_3_4	TH_SP_4
Hsu W.	Huynen I.
WE2_3_1	TH1_3_2
Hu SB.	Hwang GJ.
TU1_2_4, TU2_1_3	TU2_1_3

```
WE-P16
Hwang H.
   TU2_1_5
                           Jagadish C.
Iannaccone G.
                               TU-P21
                           Jäger G.
   TH2_3_3, TU3_1_2
Ichikawa A.
                               WE2_2_4
  WE1_3_2
                           Jalil M.B.A
Imaizumi Y.
                               TU-P38
   WE1_3_2
                           Jamitzky F.
Imaizumi Yoshiaki
                               TU1_3_3
   TU1_3_4
                           Jancu J.-M.
                               TU-P43
Imre A.
   WE1_2_1
                           Janes D.B.
In H.J.
                               TH1_2_5, TU2_2_6,
   TH3_2_4
                               WE1_1_2
Ionescu A.M.
                           Jang M.
   TH1_3_3
                               TU-P12
Islam M.S.
                           Jaroenapibal P.
  WE1_3_1
                               TH1_1_2
Izumida T.
                           Javier A.M.
```

```
WE3_3_1, WE3_3_3
Jeffery C.M.
  WE2_1_4
Jeon S.
   TU2_1_5
                          Kamins T.I.
Jeong G.-H.
                           WE1_3_1
   WE-P15, WE-P16
                          Kamio T.
Jeong N.J.
                             WE-P30
   WE-P8
                          Kang D.
Jeong Y.S.
                             TU-P4
   TU2_1_5, WE-P16
                          Kanje M.
Ji H.-H.
                             WE2_3_3
   TU1_2_4
                          Karrai K.
Jia C.
                             TU-P20, TU-P25
   TU-P11
                          Kasama Y.
Jianfei J.
                             WE-P16
   TU-P1, TU-P11
                          Katayama Y.
Johansson F.
                             TH2_2_4
   WE2_3_3
                          Kato T.
Jullien G.A.
                             WE-P15
  WE3_2_3
                          Kavanagh K.L.
Jurga S.M.
                             TU2_3_2
   TH3_2_4
                          Keles Y.
                             WE-P14
```

Keller J.	Kim M.
TU1_2_3, WE2_2_5	TU2_3_4
Kempe A.	Kim M.K.
TU-P37	TU2_1_5
Khitun A.	Kim S.
TU1_2_2, WE2_1_2	WE2_2_3
Khondaker S.I.	Kim SH.
WE-P28	WE-P17
Khopade A.J.	Kim US.
WE-P19	TU1_2_4
Kienle D.	Kim Y. K.
TH1_2_3,WE-P13	WE-P3
Kim B.	Kirchner C.
TU-P4	WE3_3_3
Kim C.W.	Klimeck Gerhard
TU2_1_5	TU3_1_1
Kim DB.	Knapp H.F.
TU1_2_4	WE-P14
Kim H.	Koch M.
TU-P22	TH_SP_5, <b>TU-P40</b> ,
Kim J.	TU-P41
TU-P4	Kogge P.M.
Kim J.H.	WE2_1_5
TU2 1 5	Kolasa B.

TU-P15 Konstantatos G. TU1_2_1 Koswatta S.O. TU2_2_6 Kotthaus J.P. WE-P6 Krahne R. TU-P33 Kraus P.A. TU1_2_5 Kress A. WE2_2_6	TU-P29, WE3_3_1, WE3_3_3  Kühn O. TU-P17  Kuo SY. TH2_2_5, WE-P33, WE-P38  Kuo Y. TU-P10  Kutter Christoph WE_PL_1  Kwon SK. WE-P17
Kretzschmar I. TH1_2_1, TH1_3_6 Kreupl F. TU1_1_2 Krishnan Shoba	L
TU3_2_6 Krishnardula V. TU-P46 Krueger F.A. WE-P20 Kudera S.	La Rocca G. C.  TU-P43  Lackinger M.  WE2_2_1  Lageweg C.  TH2_2_6

Lai M.Y.	Lee G.
TU-P47	TU-P15
Lakshmanan V.H.	Lee HD.
TU2_3_1	TU1_2_4
Lambacher M.	Lee HS.
WE-P6	TU1_2_4
Latessa L.	Lee JG.
TU1_1_3	TU1_2_4
Lawrence W.E.	Lee J.W.
TH1_1_4	TU2_1_5, WE-P36,
Laws G.M.	TH1_3_1
TH2_1_3	Lee K.
Leathem B.	WE1_1_2
TU2_3_2, TU-P19	Lee K.H.
Leblebici Y.	WE3_2_1
TU-P13	Lee MH.
Lee C.	WE-P3
TU-P4	Lee S.
Lee CT.	TU-P12
TU-P18	Lee S.J.
Lee E.	WE-P8
TU1_3_1	Lee T.
Lee ES.	TH1_2_1
WF-D17	Lent CS

```
WE2_1_5
                             TU3_2_2
                          Liebau M.
Leoni R.
   TU3_1_2
                             TU1_1_2
Lever P.
                          Lieberman M.
   TU-P21
                             WE2 3 4
Levina L.
                          Liedl T.
   TU1_2_1
                             WE3_3_3
Li E.
                          Lim S.-H.
   TU3_2_5
                             TU2_1_2
                          Lin C.-F.
Li
   G.
                             TU2_3_3, TU-P42
   TH2_1_2, TH2_1_5,
   TH3_2_2, TU-P36
                          Lin H.
Li S.-R.
                             TU-P34
   WE2_1_3
                          Lin H.Y.
  W.J.
Li
                             TU-P31
                          Lin P.-I.
   TH2_1_5, WE1_3_6
Li Y.
                             TU-P30
   TH1_2_2, TH1_3_1,
                          Lin T. K.
   TU-P39, WE-P36
                             WE2_3_1
                          Ling T.G.I.
Liang E.-Z.
  TU-P42
                             WE2_3_3
Liang G.-C.
                          Linß G.
 TH1_2_3
                            TU-P17
Liang Q.
                          Liu C.
```

TU-P46	TH2_3_6, TU1_1_3,
Liu J.	WE1_3_3, WE-P11,
TU1_2_2	WE-P5
Liu P.	Lundstrom M.
WE1_3_2, WE2_3_2	TH2_2_1
Lodha S.	Lusth J.C.
TH1_2_5	TH2_3_5
Lombardo G.	Luzzi D.E.
WE-P22	TH1_1_2
Lombardo M.	Lyding J.
WE-P22	TU2_2_5
Lorenz H.	Lyding J.W.
TU-P25	TU1_1_4
Lu CY.	Lyshevski M.A.
WE-P33, WE-P38	TH2_1_4, TU-P16,
Lu D.	WE-P10, WE-P21
TH1_2_2	Lyshevski S.E.
Lu J.	TU-P16, TU-P7, TU-P8,
TU-P10	WE-P20
Luan PG.	
TU-P18	
Ludwig F.	N //
TH_SP_8	IVI
Lugli P.	

Macucci M.	Martorana B.
WE1_1_4	TU-P27
Maeda K.	Maruccio G.
WE1_3_2	TU3_2_4, TU-P33,
Mahapatra S.	WE-P2
TH1_3_3	Maruyama H.
Manna L.	WE1_3_2
TU-P29, TU-P33	Mastylo R.
Manna L.	TU-P17
WE3_3_1	Mateos J.
Manske E.	TU3_1_4
TU-P17, WE2_2_4	Mathis W.
Månsson A.	WE3_2_2
WE2_3_3	Maximov I.
Manus S.	WE2_3_3
WE-P23	Mazumder P.
Marchi A.	WE2_1_3, WE-P39
TU3_2_1	Mazur M.
Martelli F.	WE3_2_3
WE2_2_2	Mazzeo M.
Mårtensson T.	WE3_1_3
WE2_3_3	McLelland H.
Martiradonna L.	TU3_1_3
WE3_1_3	Merchant T.

TH1_3_4	TU2_1_2
Merlo V.	Moran D.
WE-P12	TU3_1_3
Mertelj T.	Moskovits M.
WE1_2_2	TH1_3_6
Metlushko V.	Mourokh L.G.
WE1_2_1	WE-P1
Meyer C.	Müller B.H.
TU-P25	TU-P6
Meyer E.	Munden R.
WE-P14	TH1_3_6
Meyyappan M.	Muralidhar R.
TU3_2_6	TH1_3_4
Michel B.	Murgia M.
TU1_2_3, WE2_2_5	WE1_2_2
Milas M.	Muzic M.
WE-P14	TU1_2_3
Mimura H.	
WE-P16	
Möhwald H.	N.I.
WE-P19	IV
Montelius L	
WE2_3_3	Nakajima M.
Moon J. T.	TU-P35

Narayanan A. TU-P23 Nehse U. TU-P17 Nelson Bradley J. WE1_3_4 Neo Y. WE-P16	Nötzel R. TU2_3_5 Noy A. TU3_2_3 Nunziante Cesaro S. WE-P8 Nyathi J. WE-P43
Ng C.  WE1_3_2  Ng V.  TU2_2_3, TU-P38	O
Ngo Quoc TU3_2_6 Nicolais L. TU-P27 Nilsson S.G. WE2_3_3 Nirschl T. TU-P14 Noguchi T. WE2_3_2 Notargiacomo A. TU3_1_2	Oh SY.  TU1_2_4 Ohlberg D.A.A.  WE2_2_3 Ohno Hideo  WE1_2_4 Olapinski M.  WE-P23 Olsen C.S.  TU1_2_5 Omote K.

WE-P16 Orlanducci S. WE1_3_3, WE-P11, WE-P12, WE-P8 Orlov A. WE1_2_1	Parikh C.  TH1_3_4  Park H.  TU2_1_5  Park H.G.  TU3_2_3  Park JH.  TU-P22
P	Park N. <b>TU2_1_4</b> Park SH.
Pacha C.	TU1_2_4 Park W. TU-P4 Park W.I. TU2_3_4 Park Y. TU2_1_5 Park YW. WE-P16 Parravicini G.P TU-P45 Pastorino L.
WE3_3_3, TU-P29, WE3_3_1	TH_SP_6

Patent E.A.	Popescu P.D.
TU2_3_5	TU2_3_2
Pecchia A.	Popov V.V.
TU1_1_3, WE-P5	TU-P5
Pellegrino T.	Porod W.
WE3_3_1, WE3_3_3	TH2_3_6, WE1_2_1,
Perlo P.	WE2_1_1
TU-P27	Pramanik S.
Persson F.	TU3_1_5
WE2_3_3	Prasanth R.
Pettenghi H.	TU2_3_5
WE-P32	Principe J.C.
Phillips J.B.	TH2_2_2
TH_SP_6	Prinz E.
Piazza V.	TH1_3_4
TU3_1_2	
Pichonat E.	
TH1_3_2, TU3_1_4	
Pingue P.	O
TU3_1_2	
Plank C.	Ovintana IM
TH_SP_7	Quintana J.M.
Pompa P.P.	WE-P32
WE-P2	

#### TH2\_2\_1, WE-P37 Reale A. WE1\_3\_3, WE-P11, **WE-P12** Ragan R. Reed M. A. WE2\_2\_3 TH1\_2\_1, **TH1\_3\_6** Railton C.J. Reggiani S. WE3\_1\_2 TU3\_2\_1 Rakshit T. Regoliosi P. TH1\_2\_3 WE1\_3\_3, WE-P12 Raman S. Rehn U. **TU-P23 WE-P24** Rao R. Rendlen J. TH1\_3\_4 TU2\_2\_2 Rarity J.G. Renz T. WE3\_1\_2 TU-P7 Rashmi Reuter A. TH1\_3\_2 WE3\_3\_2 Rauch T. Ricci D. WE-P44 **WE-P18** Ravaioli U. Riminucci A. TH1\_2\_2 WE1\_2\_2 Ray A.K. Rinaldi R. **WE-P28** TU3\_2\_4, TU-P33, Raychowdhury A.

WE-P2	Ruani G.
Robertson J.	WE1_2_2
WE2_2_2	Rubini S.
Roelens Y.	WE2_2_2
TH1_3_2, TU3_1_4	Rubio-Sierra F.J.
Roman C.	TU-P37
TH1_1_3	Rückert U.
Rosner B.	WE-P43
TU2_2_2	Rudan M.
Rossi M.	TU3_2_1
WE-P12	Rudolph C.
Rossow M.	TH_SP_9
TH1_3_4	Ruggiero C.
Rotkin S.	TH_SP_6
TH1_2_2	Ruppalt L.B.
Roukes M.L.	TU1_1_4
TH1_1_5	Ruppel L.
Roy G.	WE-P4
TH2_3_2	Ryu I.S.
Roy K.	WE-P8
TH2_2_1, WE-P37	
Roy S.	
TH2_3_2, WE-P31,	C
WE-P43	

Sarwe E.-L. Sabharwal C.L. WE2\_3\_3 Savvidis P.G. TH2\_1\_2 Sadd M. **TU-P15** TH1\_3\_4 Sberveglieri G. Saeed A. **TU-P24** TH2\_1\_5, TH3\_2\_2, Scappucci G. **TU-P36** TU3\_1\_2 Scarpa G. Sakamoto M. **WE-P30** TU1\_1\_3 Salviati G. Schäfer G. **TU-P24 TU-P28** Samuelson L. Scheible D.V. **WE2\_3\_3**, TU2\_1\_1 TH1\_1\_1 Sanders A. Schilinsky P. **WE-P44** TH1\_3\_6 Saraniti M. Schmid A. TH2\_1\_3 **TU-P13** Sargent E.H. Schmidt H. TU1\_2\_1 **TU-P28** Sarraf H. Schmitt-Landsiedel D. **TU-P32 TU-P14** Sarveswaran K. Scholz R. WE2\_3\_4 **TU-P43** 

Schubert U.S.	Serrao S.
WE-P6	WE-P22
Schuh D.	Sessa V.
WE2_2_6	WE-P12
Schulhof G.	Sharma S.
WE3_2_3	WE1_3_1
Schulten K.	ShenG.R.
TH1_2_2	WE2_3_1
Schulz R.	Shi D.
WE2_2_6	TU2_2_5
Scott A.D.	Shi Q.W.
TU2_2_6	TH1_3_5
Seidel R.	Shile R.
TU1_1_2	TU2_2_2
Seidl N.	Shin JK.
TU-P40	TU-P22
Seifer W.	Shin M.
WE2_3_3	TU-P12
Seminario J. M.	Shukla S.K.
TH1_2_4, WE-P7	WE-P34,WE-P35,
Seo S.	WE-P41
TU2_1_5	Simmel F.C.
Seo Y.S.	WE3_3_2, WE-P23
WE-P8	Sinah K.

**TU-P26** TU3\_1\_1 Singh N. Stanley C. TU2\_2\_4, TU-P38 TU3\_1\_3 Stark M. Sitti M. TH3\_2\_1, TU1\_3\_2 TU1\_3\_3, WE1\_3\_5 Skaug E.A. Stark R. W. TH2\_3\_5 WE1\_3\_5, TU1\_3\_3, Smirnov A.Yu. **TU-P37** WE-P1 Steimle R.F. Smith H.I. TH1\_3\_4 TH3\_2\_4 Steinhoegl W. Song K.S. TU1\_1\_2 WE-P8 Stemmer A. Sorin D.J. WE1\_3\_5 TU-P9 Stern E. Soumetz F.C. TH1\_3\_6 TH\_SP\_6 Stimpfle A-Sperling R.A. TU3\_2\_6 WE3\_3\_1 Stöckli T. **WE-P14** Speyer G. Stoker M. WE1\_1\_3 Sgalli O. TH1\_3\_4 **TU-P25** Stomeo T. Srivastava P. WE3\_1\_3

Straub S.	WE1_2_2
TH1_3_4	Tamburri E.
Strauss D.J.	WE-P11, WE-P12,
TU-P28	WE-P8
Su C.C.	Tan H.H.
TU-P31	TU-P21
Su YS.	Tang CS.
TU2_3_3	TH1_3_1
Sulieman M.	Tang H.
TH2_2_3, WE-P40	WE-P36
Sun KJ.	Tang J.M.
TU2_3_3	TH2_1_3
Svizhenko A.	Tang Z.K.
WE1_1_1	TU3_2_2
Swift C.	Tao W.
TH1_3_4	TH2_1_2
	Tarn TJ.
	TH2_1_2, TH2_1_5
<del></del>	Tatenuma K.
	WE2_3_2
	Teperik T.V.
Tafazzoli A.	TU-P5
	Terranova M. L.
<b>TU1_3_2</b> Taliani C.	WE-P8, WE1_3_3,
ranan U.	

WE-P11, WE-P12 Thalhammer S. **WE-P27** Thayne I. TU3\_1\_3 Thommen V. **WE-P14** Thoms S. TU3\_1\_3 Thornton T.J. TH2\_1\_3 Todaro M.T. WE3\_1\_3 Tohji K. **WE-P15** Töpfer S. **TU-P17** Torre A.D. **TU-P33** Townsend W.J. **WE-P42** Tsai I.-M. TH2\_2\_5 Tsai L.-N.

WE2\_3\_1
Tsukerman I.
TU2\_2\_1
Tzeng Y.
TU-P46

U

Uccelli E.

WE2\_2\_6

Uemura T.

WE-P39

Ulstrup J.

WE1\_1\_5

Unger E.

TU1\_1\_2



MAIN

SESSIONS

ORAL

POSTER I

POSTER II

```
Valentini F.
                          Vos H.
   WE-P8
                              WE1_1_5
van der Tol J.J.G.M.
   TU2_3_5
van Veldhoven P.J.
   TU2_3_5
Vasileska D.
 TH2_3_4
                           Waldauf C.
Vassiliadis S.
                             WE-P44
   TH2_2_6
                          Wallart X.
Verma L.K.
                            TU3_1_4
   TU2_2_3
                          Walus K.
Visconti P.
                              WE3_2_3
   TU3_2_4, TU-P33
                          Wang C.R.
Vogel D.
                              TU-P6
   TU1_2_3, WE2_2_5
                          Wang H.-W.
Vogel V.
                              TH2_2_5
   TH2_1_1
                           Wang I.-S.
VogI W.
                              TU-P22
   TH3_2_1
                          Wang K.L.
Voisin P.
                              TU1_2_2, WE2_1_2
  TU-P43
                          Wang P.-F.
von Klitzing K.
                            TU-P14
   TU_PL_1
                          Wang S.-A.
```

WE-P33, WE-P38	Witte G.
Wang W.	WE-P4
TH1_2_1	Wolf B.
Wang Y.L.	TH_SP_1, <b>TU-P40</b> ,
TU-P47	TU-P41
Watling J.R.	Wöll C.
TH2_3_2	WE-P4
Wechsler D.	Wolter J.H.
TH_SP_2	TU2_3_5
Wehrspohn R.B.	Woolard D.
WE-P24	WE3_2_4, TH1_2_4
Wei C.M.	Wu SJ.
TU-P47	TU-P30
Wei J.H.	Wu Y.
TU-P47	TH1_3_6
Weyh T.	Wunderle B.
TH_SP_11, TU-P40,	WE2_2_5
TU-P41	Wybourne M.N.
White B.E. Jr.	TH1_1_4
TH1_3_4	
Wilk S.	
TH2_1_3	V
Williams R. S.	X
WE2_2_3, WE1_3_1	

```
Xi
                          Yellen B.
   N.
                             TU2_2_1
   TH2_1_2, TH2_1_5,
   TH3_2_2, TU-P36
                          Yeo I.-S.
                             TU2_1_2
                          Yi G.-C.
                             TU2_3_4
                          Yoo Y.-E.
                             WE-P17
                          Yu S.-M.
Yang Cary Y.
                             TH1_3_1
 TU3_2_6
                          Yu S.P.
Yang J.J.
                             WE-P8
   TU-P31, TU-P18
                          Yun J.-G.
Yang K.
                             TU1_2_4
 WE-P39
Yang S.
   TU3_2_5
Yang Y.-H.
  TU-P30
Yang Y.T.
 TH1_1_5
                          Zäh M.F.
Yanik Ahmet Ali
                             TH3_2_1
                          Zappettini A.
   TU3_1_1
                           TU-P24
Yater J.
```

Zayko Yu.N.

TH1\_3\_4

```
TU-P5
Zha M.
  TU-P24
Zhang H.
   TU2_2_2, WE-P39
Zhang J.
   TH1_3_6, TH2_1_5,
  TU-P36
Zhang M.
   TH2_1_2, TH2_1_5,
   TU3_2_2
Zhang S.
  TU2_1_4
Zhao G.
   TU2_3_5
Zhao Peiji
  TH1_2_4
Zhou L.
   WE1_2_1
```





## Office of Naval Research

Site Search

search

**ONR Keyword** 

keywords

Go

Office of Naval Research

Public

**About ONR** 

Workshops

**Visiting ONR?** 

**Special Events** 

Conferences &

Jobs

**FOIA** 

July 26, 2004 Site Map

Resources

Go

**Contact Us** 



Researchers often look at unique abilities in insects, fish and animals for novel approaches to naval problems. Courtesy of USDA.

URI/Education /

**University Business** 

HBCU/MI

**AwardWeb** 

**AdminWeb** 

**Affairs** 

The Office of Naval Research coordinates, executes, and promotes the science and technology programs of the United States Navy and Marine Corps through schools, universities, government laboratories, and nonprofit and forprofit organizations. It provides technical advice to the Chief of Naval Operations and the Secretary of the Navy and works with industry to improve technology manufacturing processes.

The rotating images at left illustrate some of the science and technology that ONR supports. Visit our Media area for more information.

#### You're Invited!

	Acquisition	Students & Teachers	Military	Media
	Contracts & Grants	<u>Focus</u>	Future Naval	Leads & Releases
ı			Capabilities	
	BAAs	Science Fair		Image Gallery
ı	DAAS		<u>Tech Solutions</u>	
	Business and	<u>Cyberscientist</u>		<u>Publications</u>
ı	Partnership		<u>Swampworks</u>	
ı	Opportunities	<u>Teachers' Corner</u>		Nobel Laureates
н	<u>Opportunities</u>		ONR Global	

- Fleet/Force

**Naval Reserve** 

Commericial

Transition Officer

Technology

(CTTO)

#### **ONR Science & Technology Departments**

#### Information, Electronics & Surveillance (Code 31)

- · Electronics
- · Math, Computer and Information Sciences
- · Surveillance, Communications, and Electronic Combat

## Ocean, Atmosphere & Space (Code

- · Sensing and Systems
- · Processes and Prediction

#### Engineering, Materials & Physical Science (Code 33)

- · Physical Sciences
- · Materials
- · Mechanics and Energy Conversion
- · Ship Hull, Mechanical & Electrical **Systems**
- · Navy S&T Ship Office

#### Human Systems (Code 34)

- · Medical and Biological Division
- · Cognitive, Neural and Social **Division**

#### **Naval Expeditionary Warfare** (Code 35)

- · Strike Technology
- · Expeditionary Warfare Operations
- · Technology Watch and Evaluation

## Media Advisory: Naval Research in the 21st Century: Dilemmas and Solutions

#### Naval Technology Achievement Award 6/24/2004

Media Advisory: See Live Demos of a Remote-Operated Patrol Boat, Language Translator & Virtual Reality Gear Aboard the Afloat Lab During NYC Fleet Week Visit 5/20/2004

**Brain Control** 5/11/2004

7/21/2004

Waste Not, Want Not 5/11/2004

Media Articles

Mowing Back Antennas

**All Articles** 

Contact Media

#### **Industrial and Corporate** Programs (Code 36)

- · Manufacturing
- **Product Innovation**
- · Corporate Programs
- · SBIR/STTR

5/11/2004

 $\underline{ \mbox{Hybrids on the High Seas; Fuel Cells For Future Ships}}$ 

2/26/2004

"Chatting" in Iraq

2/26/2004

NOAA and U.S. Navy Uncover Secrets of Lost Civil War Submarine USS Alligator

12/15/2003

#### Accessibility at ONR

This is an Official <u>U.S. Navy Web site</u> - <u>GILS Registration #</u>(UID): 23916 (Navy Web Sites)

Content Author: WebDesk Notices: Links | Cookies Page Modified: July 15, 2004

<u>Privacy & Security Notice</u> | <u>Privacy Advisory Notice</u> (regards security and collection of personal information)

Printer-friendly page



#### SIEMENS

Deutsch

Site Map | Contact Us

Home | Products, Solutions & Services | News & Events | Investor Relations | Press | Jobs & Careers | About Us



#### **Legal Information**

- Corporate Information
- Privacy Policy
- → Terms of Use
- → Digital ID

## Global network of innovation

World-class solutions in electrical engineering and electronics

Explore Siemens

## Go

#### Siemens Worldwide

Choose a country

Siemens in the U.S.

Look for mobile phones Find fixed-line phones

→ Siemens in Germany

See what's new Get key information

Discover Siemens worldwide Search for jobs

and figures

## Consumer I want to...

→ Products, solutions and services for business customers. View by:

Category

**Business** 

- Industry
- → Product name



→ Mobile phones, computers, home appliances and more.



Competitive paper production

Limited renewable resources, increasing

environmental protection and quality requirements, a worldwide surplus supply. How can paper manufacturers stay competitive? Check out our pulp & paper solutions. 

more



LIFEBOOK P – greater mobility

The LIFEBOOK P notebook is one of the lightest yet fully

functional notebooks around. It also offers a widescreen display, the latest Intel® Centrino™ Mobile Technology and a variety of interfaces. → more

#### Siemens Journal



Where do new ideas and innovations come from? What innovations does communications technology offer? From which advances in medical technology do we profit the most? Read the answers to these questions in the July issue of Siemens Journal!

→ more

#### Spotlight

Siemens Journal
Online Magazine

#### Annual Report 2003



Corporate Responsibility Report 2003

#### Commerce

- → Buy from Siemens
- → Sell to Siemens
- → Finance with Siemens

#### **Press**

Jul 21, 2004 | Joe Kaeser named new Siemens strategy head → more

Jul 21, 2004 | Siemens: Management team for new IC Group complete → more



© Siemens AG 2004 - Corporate Information / Privacy Policy / Terms of Use / Digital ID



### Never stop thinking.



Product Search | FIND | Search | Home | MyInfineon | Newsroom | Contact | Sitemap

Products | Company Information | Investor Information | Careers

## Infineon Technologies AG

Infineon is a leading innovator in the international semiconductor industry. We design, develop, manufacture and market a broad range of semiconductors and complete system solutions targeted at selected industries. Our products serve applications in the wireless and wireline communications, automotive, industrial, computer, security and chip card markets. Our product portfolio consists of both memory and logic products and includes digital, mixed-signal and analogue integrated circuits, or ICs, as well as discrete semiconductor products and system solutions.

#### **Latest News**







© 1999 - 2004 Infineon Technologies AG - Usage of this website is subject to our Usage Terms.

more news...



About IEEE | Join IEEE | Search IEEE | IEEE Home

**AdCom** 

**Conferences** 

**Publications** 

Nanotechnology
Virtual Community

Home



The IEEE Nanotechnology Council is a multi-disciplinary group whose purpose is to advance and coordinate work in the field of Nanotechnology carried out throughout the IEEE in scientific, literary and educational areas. The Council supports the theory, design, and development of nanotechnology and its scientific, engineering, and industrial applications.

The Nanotechnology Council is part of Division I - Circuits and Devices and is made up of 20 member societies:

- 1. Aerospace & Electronic System Society (AES)
- 2. Antennas & Propagation Society (AP)
- 3. Circuits & Systems Society CAS)
- 4. Communications Society (COM)
- 5. Components, Packaging, & Manufacturing Technology Society (CPMT)
- 6. Computer Society (C)
- 7. Control Systems Society (CS)
- 8. Electron Devices Society (ED)
- 9. Engineering in Medicine & Biology Society (EMB)
- 10. Electromagnetic Compatibility Society (EMC)
- 11. Industrial Electronics Society (IE)
- 12. Instrumentation & Measurement Society (IM)
- 13. Lasers & Electro-Optics Society (LEO)
- 14. Magnetics Society (MAG)
- 15. Microwave Theory & Techniques Society (MTT)
- 16. Neural Network Society (NN)
- 17. Reliability Society (RL)
- 18. Robotics & Automation Society (RA)
- 19. Systems, Man, & Cybernetics Society (SMC)
- 20. Ultrasonics, Ferroelectrics, & Frequency Control Society (UFFC)

If you would like to contact the IEEE Webmaster, email to webmaster@ieee.org

© Copyright 1999, IEEE. Terms & Conditions. Privacy & Security.

(j.eason@ieee.org)

URL: http://ewh.ieee.org/tc/nanotech/index.html

(Modified:23-Mar-2004)



IEEE News View All

Work Begins on IEEE Standard for Broadband Over Power Lines more

**IEEE Intelligent Transportation Systems Council Becomes 39th Society** *more* 

IEEE Neural Networks Society Changes Name to Reflect Scope more

2004 IEEE Annual Election Candidates List Available Online more

READ THE LATEST INFORMATION ABOUT THE IEEE AND OFAC more

2004 IEEE Vehicular Technology Conference (VTC-2004/Fall)
26 Sep - 29 Sep 2004 ( details )

2004 IEEE/RSJ International Conference on Intelligent Robots and Systems (IROS 2004)
28 Sep - 01 Oct 2004 ( details )

2004 IEEE Custom Integrated Circuits Conference -CICC 2004
03 Oct - 06 Oct 2004 ( details )

Submit your paper to an IEEE Conference. Call for Papers deadlines

Shop IEEE Shop



### IEEE/IEE Electronic Library (IEL)

The IEEE/IEE Electronic Library provides libraries and research professionals a single source to almost a third of the world's current electrical engineering and computer science literature. <u>find</u> out more

## IEEE Member Digital Library

All titles back to 1988.
Select titles to 1950.
Login

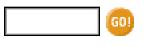
Subscribe or learn more

### Shop Amazon.com at IEEE

Support IEEE. Get Amazon.com's lowest prices. Books, CDs, Electronics and more.

Today's Hot Picks

Shop at Amazon.com



**Search Now:** 

amazon.com.



- Passives
- Semis
- Electromech
- Protection
- Power
- <u>Interconnect</u>
- Test/Measure
- <u>More ...</u>





Welcome to the IEEE	
Careers & Employment	þ
Careers & Employment	Þ
IEEE Societies	þ
IEEE Societies	$\overline{\mathbf{v}}$
Education	Þ
Education	Þ
Local Activities	þ
Local Activities	$\overline{\mathbf{v}}$
Student Resources	
Student Resources	
Volunteer Resources	
Volunteer Resources	
IEEE Annual Elections	
IEEE Annual Elections	
Advertise with IEEE	Þ
Advertise with IEEE  Advertise with IEEE	Þ
	Þ
	Þ
	► ►
	<b>&gt;</b>
	Þ
	<b>&gt;</b>
	<b>&gt;</b>
	<b>&gt;</b>
	<b>&gt;</b>

For questions or comments, please use this <u>email form</u> and select the appropriate contact. Or contact the IEEE <u>Webmaster</u> direct.

© Copyright 2004, Institute of Electrical and Electronics Engineers, Inc.

Terms & Conditions. Privacy & Security. (Modified: 01-Jul-2004)



Antragstellung | Geförderte Projekte | Sitemap | Service | Kontakt

es / [Förderung [International

[Wissenschaft Karriere]

# Herzlich willkommen bei der Deutschen Forschungsgemeinschaft

Die Deutsche Forschungsgemeinschaft ist die zentrale Selbstverwaltungseinrichtung der Wissenschaft zur Förderung der Forschung an Hochschulen und öffentlich finanzierten Forschungsinstitutionen in Deutschland.

Die DFG dient der Wissenschaft in allen ihren Zweigen durch die finanzielle Unterstützung von Forschungsvorhaben und durch die Förderung der Zusammenarbeit unter den Forschern.

#### **Aktuelles**

#### Empfehlungen für Medizinische Fakultäten

(30.07.04) Neben einer guten Grundausstattung ist vor allem die Mittelverteilung eine wesentliche Voraussetzung für Medizinischen Fakultäten, um international wettbewerbsfähig zu sein. Die DFG hat nun Empfehlungen zur leistungsorientierten Mittelvergabe (LOM) ausgesprochen.

- Pressemitteilung
- Stellungnahme

## Erstmals EURYI Award für Nachwuchswissenschaftler vergeben

(29.07.04) Die europäischen Forschungsorganisationen haben erstmals 25 Nachwuchswissenschaftler mit dem European Young Investigator Award (EURYI) ausgezeichnet. Der mit bis zu 1,25 Millionen Euro dotierte Preis soll deren Karriereweg unterstützen und zugleich die Attraktivität des europäischen Forschungsraums erhöhen.

- Weitere Informationen
- Pressemitteilung

#### DFG zum Urteil des Bundesverfassungsgerichts

(27.07.04) Mit dem heutigen Urteil zur Juniorprofessur entsteht für den wissenschaftlichen Nachwuchs ein hohes Maß an Unsicherheit. Die Juniorprofessur war der bislang konsequenteste Versuch, die frühe Selbstständigkeit des

#### Aktuelle Mitteilungen

**English** 

Das Neueste

Ausschreibungen:

Informationen für die

Wissenschaft

Pressemitteilungen

Konstituierung der Fachkollegien

Förder-Ranking 2003 Jahresbericht 2003

Stellenausschreibungen

#### Übersichten

Formulare – Merkblätter

Förderprogramme auf einen Blick

wissenschaftlichen Nachwuchses an den Hochschulen durchzusetzen. Ohne geeignete Alternativen werden gerade die besten Wissenschaftlerinnen und Wissenschaftler abgeschreckt, ihre Karriere in Deutschland fortzusetzen. Die DFG appelliert an die Länder, möglichst bald die notwendigen Rahmenbedingungen zu schaffen, um für diese Personengruppe attraktive Karrieremöglichkeiten in Deutschland auch weiterhin zu sichern.

Informationen für Wissenschaftler
Geistes- und
Sozialwissenschaftler
Lebenswissenschaftler

- Pressemitteilung
- Stellungnahme n

#### Jahrestreffen von Emmy Noether-Stipendiaten

(16.07.04) Zum dritten Mal veranstaltet die DFG ein Jahrestreffen für die Geförderten im Emmy Noether-Programm, ihrem Exzellenzprogramm für Nachwuchsgruppen. Vom 30. Juli bis 1. August treffen sich die Nachwuchswissenschaftler in Potsdam zum Erfahrungsaustausch. Im Rahmen eines wissenschaftspolitischen Abends wird Professor Julian Nida-Rümelin vortragen und für eine Diskussion zur Verfügung stehen.

- Veranstaltungsprogramm
- Mehr über das Emmy Noether-Programm

d